Serial EEPROM Series Standard EEPROM

MicroWire BUS EEPROM (3-Wire)

BR93G56xxx-5 Series

General Description

BR93G56xxx-5 Series is a 2 Kbit serial EEPROM of serial 3-line interface method. They are 16 bit organization and CS PIN is the first PIN in their PIN configuration.

Features

- 3-line Communications of Chip Select, Serial Clock, Serial Data Input/Output (the case where input and output are shared)
- Bit Format: 128 x 16 bit
- Address Auto Increment Function at Read Operation
- Prevention of Write Mistake
  - Write Prohibition at Power On
  - Write Prohibition by Command Code
  - Write Mistake Prevention Circuit at Low Voltage
- Auto Erase and Auto End Function at Programming Cycle
- Data Set to FFFFh on All Addresses at Shipment

Applications

- Ordinary Electronic Equipment (such as AV Equipment, OA Equipment, Telecommunication Equipment, Home Electronic Appliances, Amusement Equipment, etc.).

Typical Application Circuit

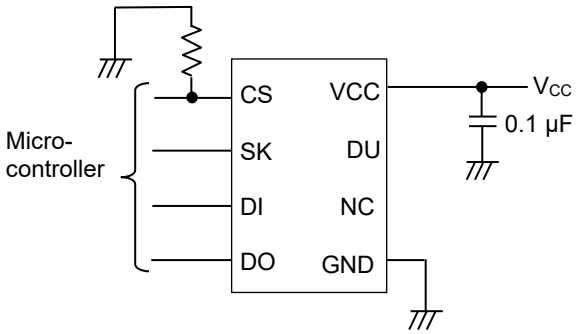

Figure 1. Typical Application Circuit

Key Specifications

- Supply Voltage(excluding WRAL): 1.7 V to 5.5 V
- Supply Voltage(WRAL): 2.5 V to 5.5 V
- Ambient Operating Temperature: -40 °C to +85 °C
- Clock Frequency: 3 MHz (Max)
- Write Time: 5 ms (Max)
- Write Cycles: 1 Million Times (Ta = 25 °C)
- Data Retention: 40 Years (Ta = 25 °C)

Packages

	W (Typ) x D (Typ) x H (Max)
SOP-J8	4.9 mm x 6.0 mm x 1.65 mm
TSSOP-B8	3.0 mm x 6.4 mm x 1.2 mm
MSOP8	2.9 mm x 4.0 mm x 0.9 mm
VSN08AX2030A	2.0 mm x 3.0 mm x 0.6 mm

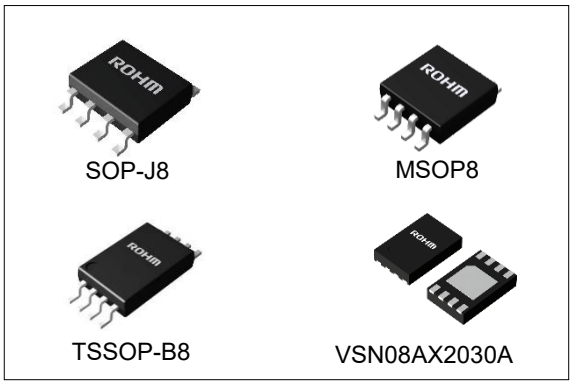

Figure 2

○Product structure : Silicon integrated circuit ○This product has no designed protection against radioactive rays.

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Pin Configurations

(TOP VIEW)

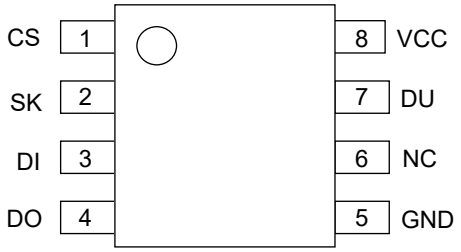

Figure 3-(a). Pin Configuration
(SOP-J8, TSSOP-B8, MSOP8)

(TOP VIEW)

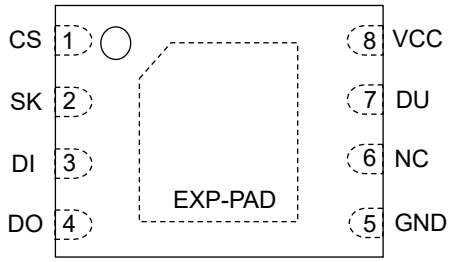

Figure 3-(b). Pin Configuration
(VSN08AX2030A)

Pin Description

Pin No.	Pin Name	Input/Output	Descriptions
1	CS	Input	Chip select input
2	SK	Input	Serial clock input
3	DI	Input	Start bit, opcode, address, and serial data input
4	DO	Output	Serial data output, READY/$\overline{\text{BUSY}}$ status output
5	GND	-	All input/output reference voltage, 0 V
6	NC	-	Non connected*(Note 1)*
7	DU	-	Don't use*(Note 1)*
8	VCC	-	Power supply
-	EXP-PAD	-	Leave as OPEN or connect to GND

(Note 1) Pin may be set to any of VCC or GND or leave as open.

Block Diagram

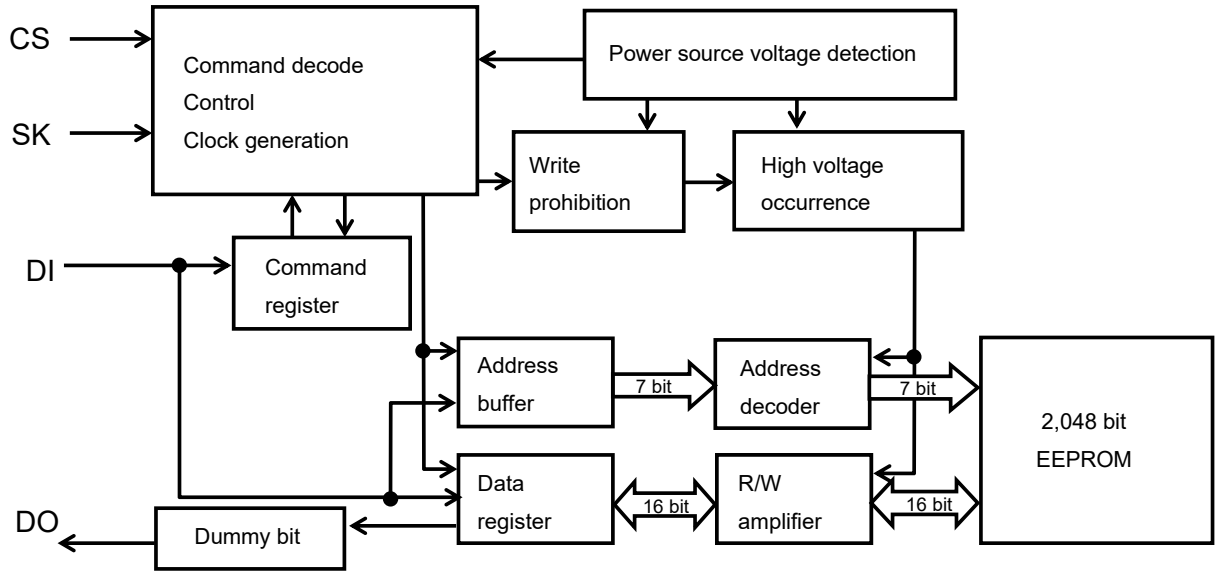

Figure 4. Block Diagram

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Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit	Remark
Supply Voltage	V_{CC}	-0.3 to +6.5	V	Ta = 25 °C
Input Voltage/Output Voltage	-	-0.3 to V_{CC}+1.0	V	Ta = 25 °C. The maximum value of input voltage is not over than 6.5 V. When the pulse width is 50 ns or less, the minimum value of output voltage is -0.8 V.
Electro Static Discharge (Human Body Model)	V_{ESD}	-3000 to +3000	V	Ta = 25 °C
Maximum Output Low Current (DO)	I_{OLMAX}	10	mA	Ta = 25 °C
Maximum Output High Current (DO)	I_{OHMAX}	-10	mA	Ta = 25 °C
Maximum Junction Temperature	Tjmax	150	°C	-
Storage Temperature Range	Tstg	-65 to +150	°C	-

Caution 1: *Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.*

Caution 2: *Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.*

Thermal Resistance*(Note 2)*

Parameter	Symbol	Thermal Resistance (Typ)		Unit
		1s*(Note 4)*	2s2p*(Note 5)*	
SOP-J8				
Junction to Ambient	θ_{JA}	149.3	76.9	°C/W
Junction to Top Characterization Parameter*(Note 3)*	Ψ_{JT}	18	11	°C/W
TSSOP-B8				
Junction to Ambient	θ_{JA}	251.9	152.1	°C/W
Junction to Top Characterization Parameter*(Note 3)*	Ψ_{JT}	31	20	°C/W
MSOP8				
Junction to Ambient	θ_{JA}	284.1	135.4	°C/W
Junction to Top Characterization Parameter*(Note 3)*	Ψ_{JT}	21	11	°C/W

(Note 2) Based on JESD51-2A (Still-Air)
(Note 3) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.
(Note 4) Using a PCB board based on JESD51-3.
(Note 5) Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt

Top	
Copper Pattern	Thickness
Footprints and Traces	70 µm

Layer Number of Measurement Board	Material	Board Size
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt

Top		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	70 µm

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Thermal Resistance(Note 6) - continued

Parameter	Symbol	Thermal Resistance (Typ)		Unit
		1s(Note 8)	2s2p(Note 9)	
VSN08AX2030A				
Junction to Ambient	θ_{JA}	299.5	77.8	°C/W
Junction to Top Characterization Parameter(Note 7)	Ψ_{JT}	42	18	°C/W

(Note 6) Based on JESD51-2A(Still-Air)
(Note 7) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.
(Note 8) Using a PCB board based on JESD51-3.
(Note 9) Using a PCB board based on JESD51-5, 7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3mm x 76.2mm x 1.57mmt

Top	
Copper Pattern	Thickness
Footprints and Traces	70µm

Layer Number of Measurement Board	Material	Board Size	Thermal Via(Note 10)	
			Pitch	Diameter
4 Layers	FR-4	114.3mm x 76.2mm x 1.6mmt	1.20mm	Φ0.30mm

Top		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70µm	74.2mm x 74.2mm	35µm	74.2mm x 74.2mm	70µm

(Note 10) This thermal via connect with the copper pattern of layers 1,2, and 4. The placement and dimensions obey a land pattern.

Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Supply Voltage	V_{CC}	1.7	-	5.5	V	READ, WEN, WRITE, WDS, ERASE, ERAL
		2.5	-	5.5	V	WRAL
Ambient Operating Temperature	Ta	-40	-	+85	°C	
Bypass Capacitor(Note 11)	C	0.1	-	-	µF	

(Note 11) Connect a bypass capacitor between the IC's VCC and GND pin.

Memory Cell Characteristics (V_{CC} = 1.7 V to 5.5 V)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Write Cycles(Note 12)	-	1,000,000	-	-	Times	Ta = 25 °C
Data Retention(Note 12)	-	40	-	-	Years	Ta = 25 °C

(Note 12) Not 100 % TESTED.

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Electrical Characteristics (Unless otherwise specified, Ta = -40 °C to +85 °C, V_{CC} = 1.7 V to 5.5 V)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input High Voltage	V_{IH}	0.7V_{CC}	-	V_{CC}+1.0	V	
Input Low Voltage	V_{IL}	-0.3*(Note 13)*	-	+0.3V_{CC}	V	
Output Low Voltage 1	V_{OL1}	0	-	0.4	V	I_{OL} = 2.1 mA, 2.7 V ≤ V_{CC} ≤ 5.5 V
Output Low Voltage 2	V_{OL2}	0	-	0.2	V	I_{OL} = 100 µA
Output High Voltage 1	V_{OH1}	2.4	-	V_{CC}	V	I_{OH} = -0.4 mA, 2.7 V ≤ V_{CC} ≤ 5.5 V
Output High Voltage 2	V_{OH2}	V_{CC}-0.2	-	V_{CC}	V	I_{OH} = -100 µA
Input Leakage Current	I_{LI}	-1	-	+1	µA	V_{IN} = 0 V to V_{CC} (CS, SK, DI)
Output Leakage Current	I_{LO}	-1	-	+1	µA	V_{OUT} = 0 V to V_{CC}, CS = 0 V
Supply Current*(Note 14)*	I_{CC1}	-	-	1.0	mA	V_{CC} = 1.7 V, f_{SK} = 1 MHz, $t_{E/W}$ = 5.0 ms (WRITE)
		-	-	2.0	mA	V_{CC} = 5.5 V, f_{SK} = 3 MHz, $t_{E/W}$ = 5.0 ms (WRITE)
	I_{CC2}	-	-	0.5	mA	f_{SK} = 1 MHz (READ)
		-	-	1.0	mA	f_{SK} = 3 MHz (READ)
	I_{CC3}	-	-	2.0	mA	V_{CC} = 2.5 V, f_{SK} = 1 MHz, $t_{E/W}$ = 5.0 ms (WRAL, ERAL)
		-	-	3.0	mA	V_{CC} = 5.5 V, f_{SK} = 3 MHz, $t_{E/W}$ = 5.0 ms (WRAL, ERAL)
Standby Current	I_{SB}	-	-	2.5	µA	CS = 0 V

(Note 13) When the pulse width is 50 ns or less, it is -0.8 V.
(Note 14) The average value during operation.

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AC Characteristics (Unless otherwise specified, Ta = -40 °C to +85 °C, V_{CC} = 1.7 V to 5.5 V)

Parameter	Symbol	1.7 V ≤ V_{CC} ≤ 5.5 V			2.5 V ≤ V_{CC} ≤ 5.5 V			4.5 V ≤ V_{CC} ≤ 5.5 V			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
SK Frequency	f_{SK}	-	-	1	-	-	2	-	-	3	MHz
SK HIGH Time	t_{SKH}	250	-	-	230	-	-	100	-	-	ns
SK LOW Time	t_{SKL}	250	-	-	200	-	-	100	-	-	ns
CS LOW Time	t_{CS}	250	-	-	200	-	-	200	-	-	ns
CS Setup Time	t_{CSS}	200	-	-	50	-	-	50	-	-	ns
DI Setup Time	t_{DIS}	100	-	-	100	-	-	50	-	-	ns
CS Hold Time	t_{CSH}	0	-	-	0	-	-	0	-	-	ns
DI Hold Time	t_{DIH}	100	-	-	100	-	-	50	-	-	ns
Data “1” Output Delay Time	t_{PD1}	-	-	400	-	-	200	-	-	200	ns
Data “0” Output Delay Time	t_{PD0}	-	-	400	-	-	200	-	-	200	ns
Time from CS to Output Establishment	t_{SV}	-	-	400	-	-	150	-	-	150	ns
Time from CS to High-Z	t_{DF}	-	-	200	-	-	100	-	-	100	ns
Write Cycle Time	$t_{E/W}$	-	-	5	-	-	5	-	-	5	ms

Input/Output Timing

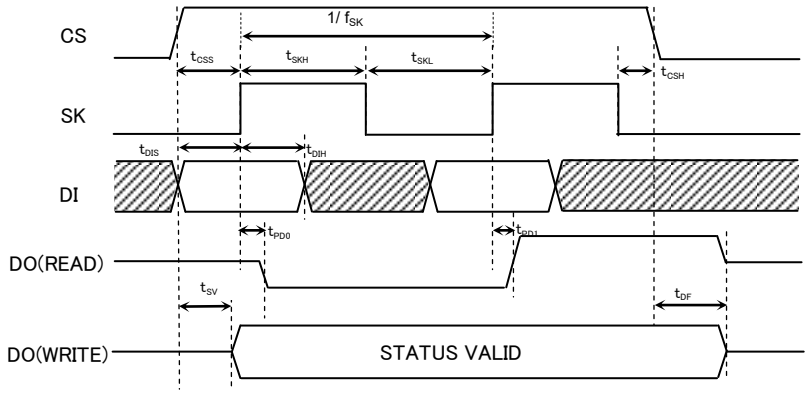

Figure 5. Input/Output Timing

・Data is taken from DI, in sync with the rise of SK.
・At READ command, data is outputted from DO in sync with the rise of SK.
・After WRITE command input, the status signal of WRITE (READY/$\overline{BUSY}$) can be monitored from DO by setting CS to HIGH after t_{CS}, from the fall of CS, and will display a valid status until the next command start bit is inputted. But, if CS is set to LOW, DO sets to High-Z state.
・To execute a series of commands, CS should be set to LOW once after completion of each command for internal circuit reset.
・$1/f_{SK}$ is the SK clock cycle, even if f_{SK} is maximum, the SK clock cycle can’t be t_{SKH} (Min) + t_{SKL} (Min).
・For Write cycle time $t_{E/W}$, please see Figure 38,39,41,42.
・For CS LOW time t_{CS}, please see Figure 38,39,41,42.

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Typical Performance Curves

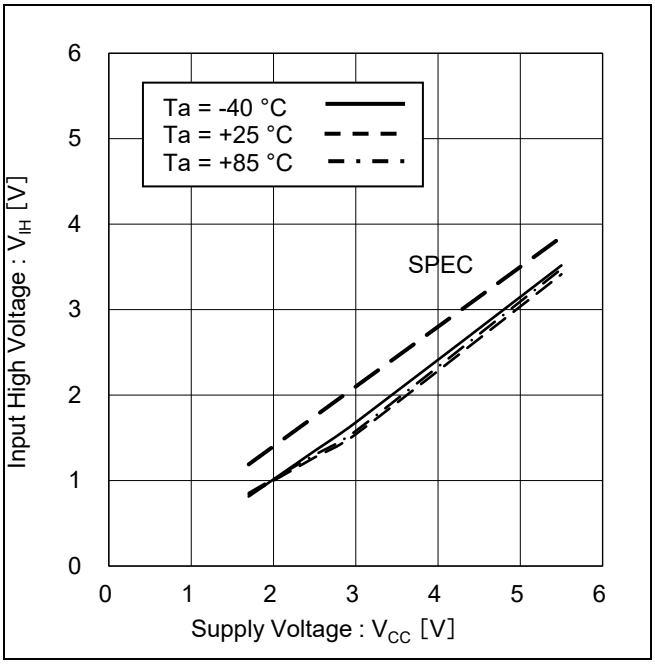

Figure 6. Input High Voltage vs Supply Voltage
(CS, SK, DI)

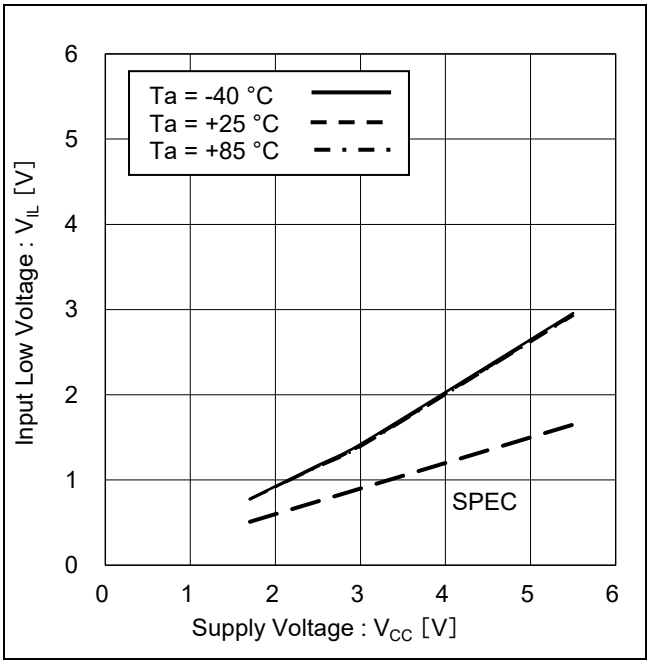

Figure 7. Input Low Voltage vs Supply Voltage
(CS, SK, DI)

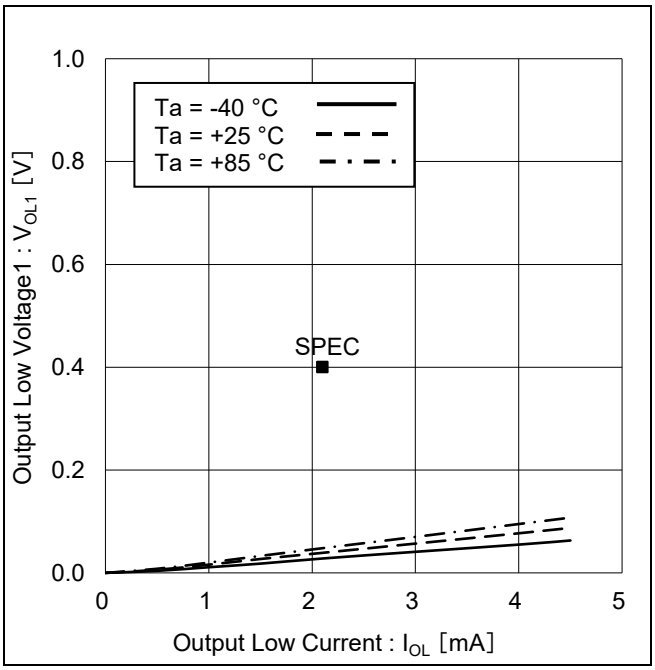

Figure 8. Output Low Voltage1 vs Output Low Current
(V_{CC} = 2.7 V)

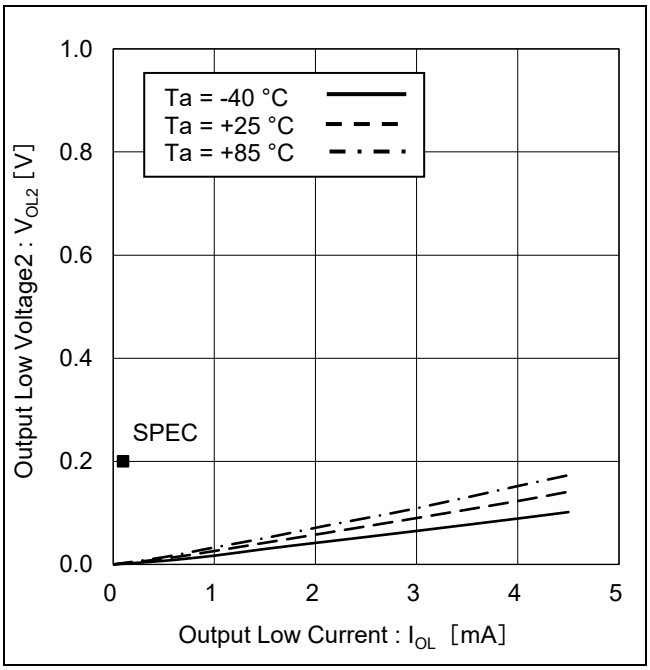

Figure 9. Output Low Voltage2 vs Output Low Current
(V_{CC} = 1.7 V)

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Typical Performance Curves - continued

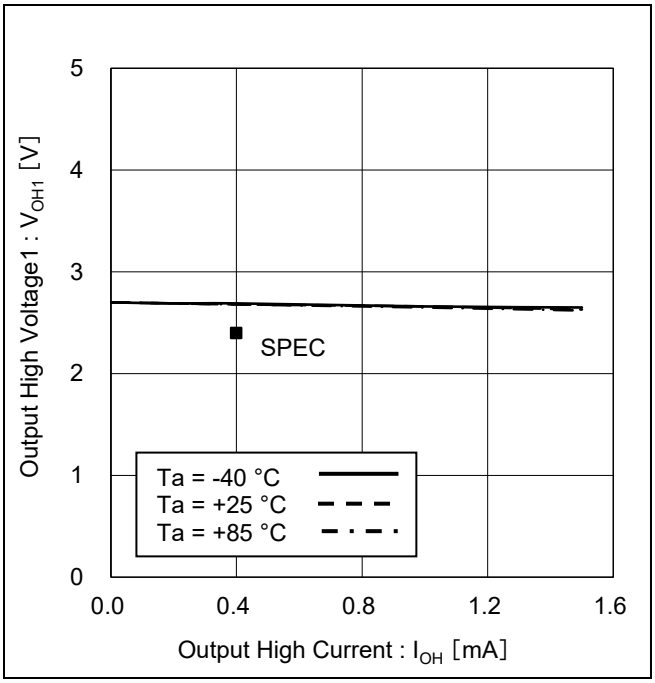

Figure 10. Output High Voltage1 vs Output High Current (V_{CC} = 2.7 V)

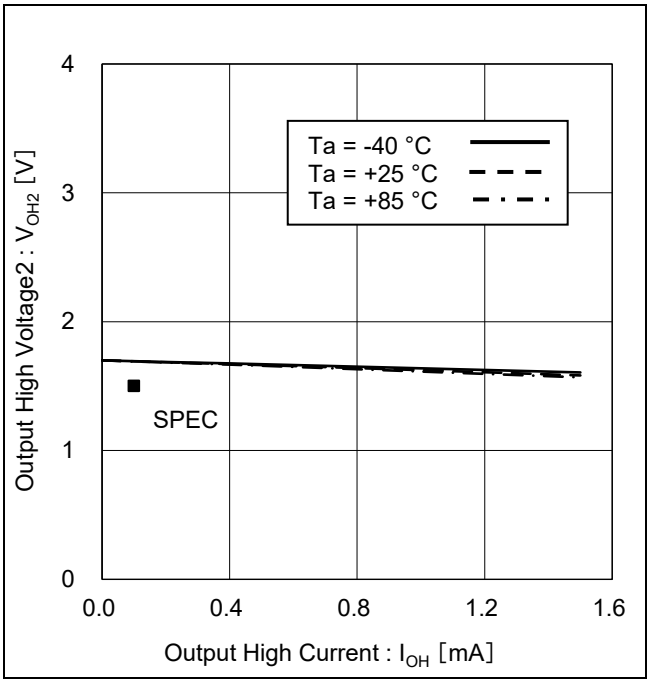

Figure 11. Output High Voltage2 vs Output High Current (V_{CC} = 1.7 V)

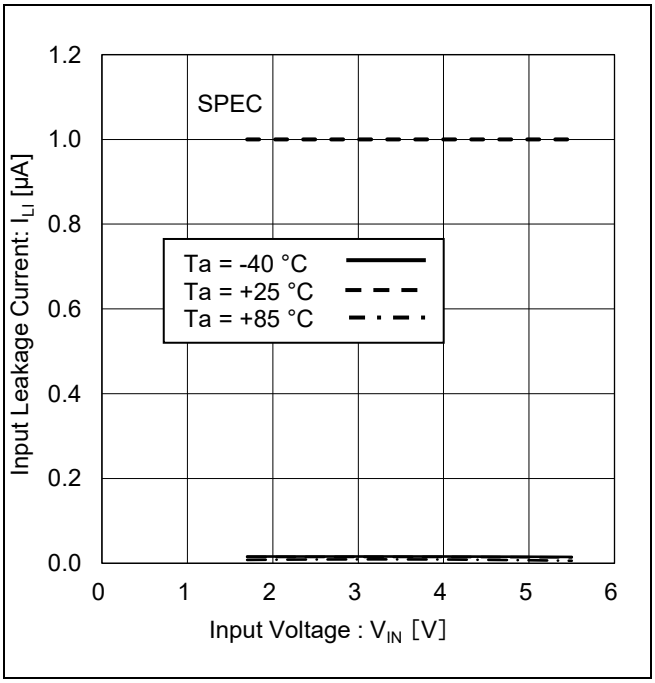

Figure 12. Input Leakage Current vs Input Voltage (CS)

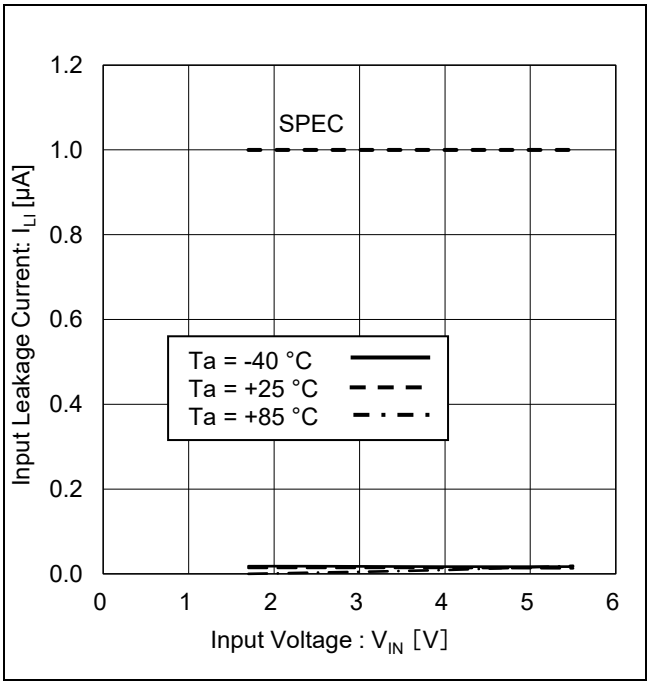

Figure 13. Input Leakage Current vs Input Voltage (SK)

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Typical Performance Curves - continued

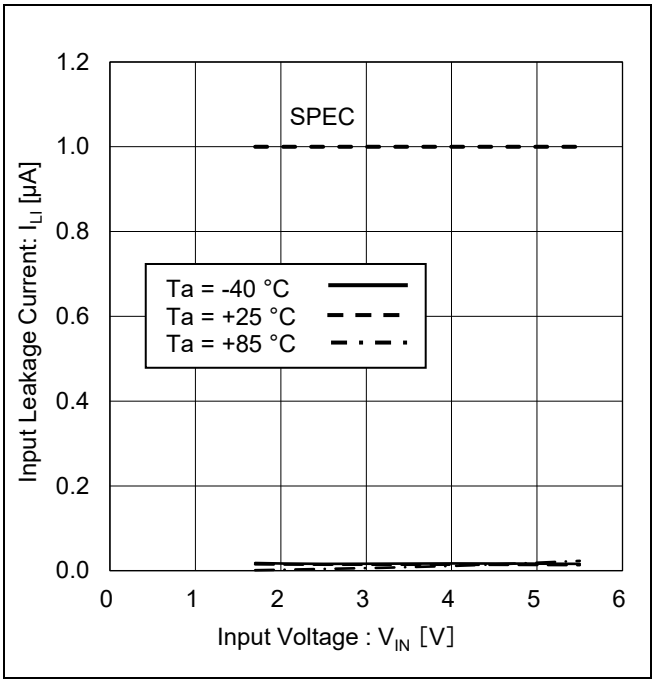

Figure 14. Input Leakage Current vs Input Voltage (DI)

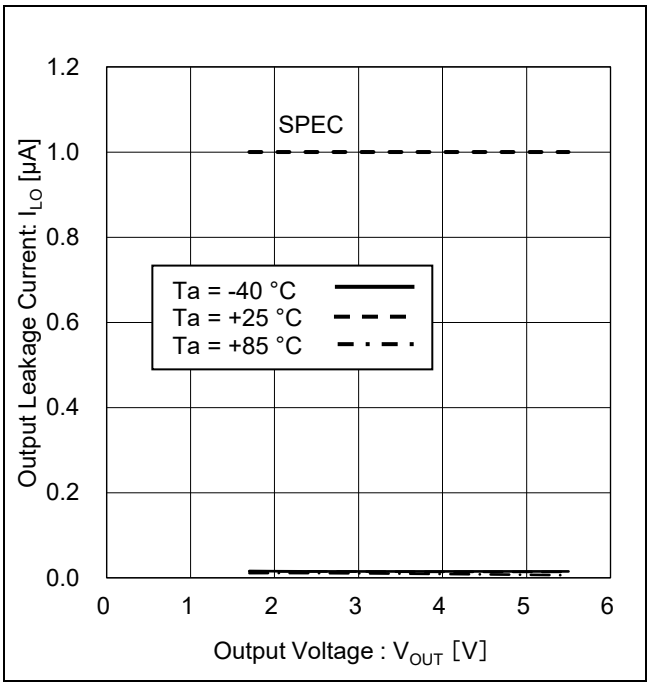

Figure 15. Output Leakage Current vs Output Voltage (DO)

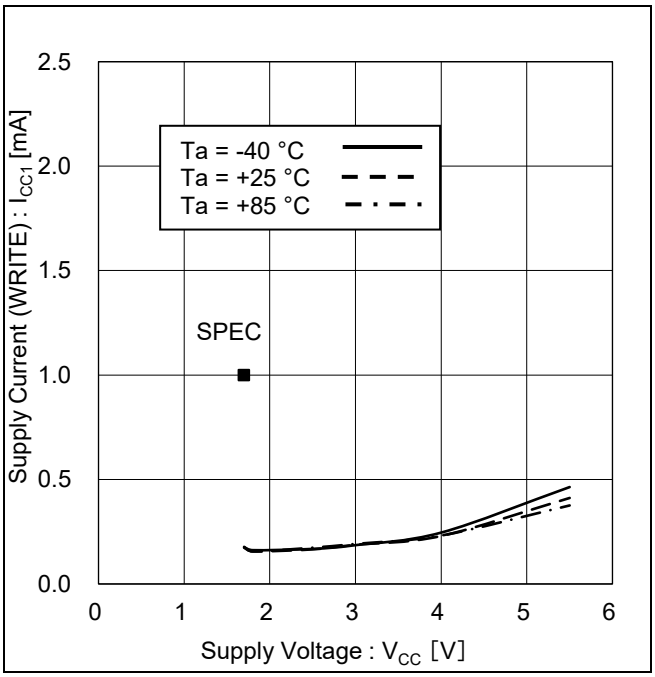

Figure 16. Supply Current (WRITE) vs Supply Voltage I_{CC1} (WRITE, f_{SK} = 1 MHz)

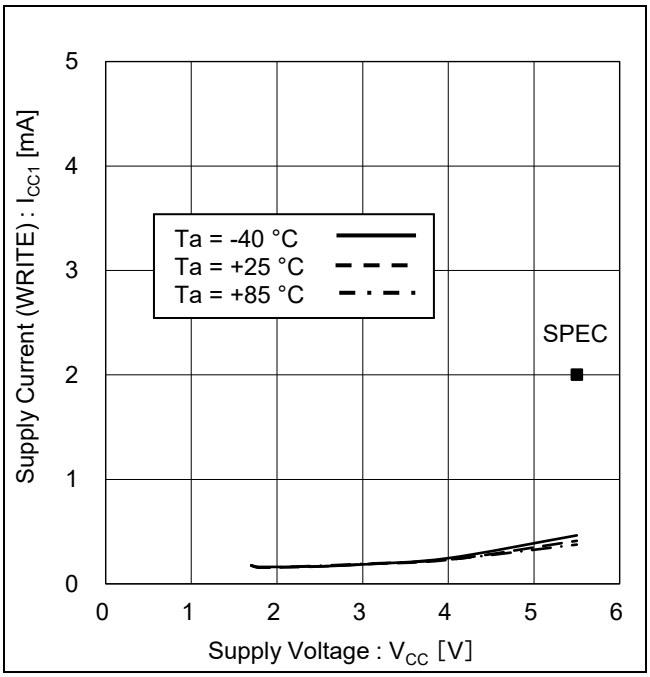

Figure 17. Supply Current (WRITE) vs Supply Voltage I_{CC1} (WRITE, f_{SK} = 3 MHz)

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Typical Performance Curves - continued

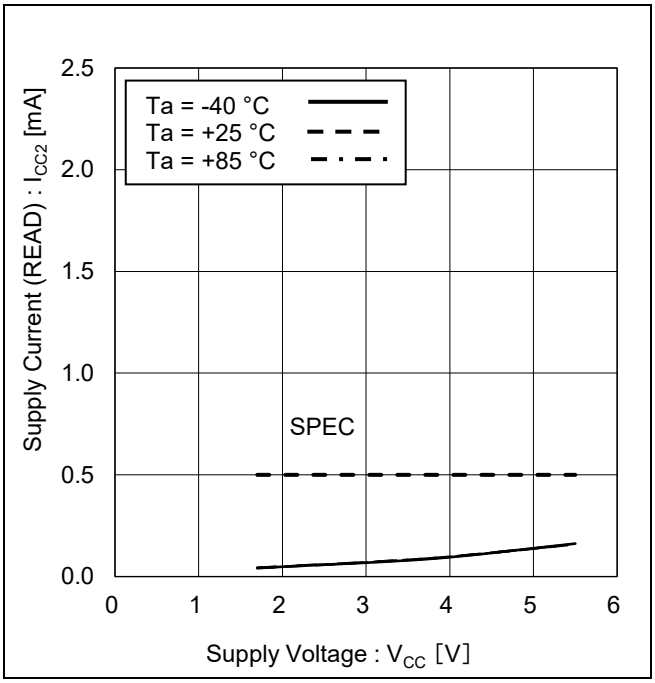

Figure 18. Supply Current (READ) vs Supply Voltage
I_{CC2} (READ, f_{SK} = 1 MHz)

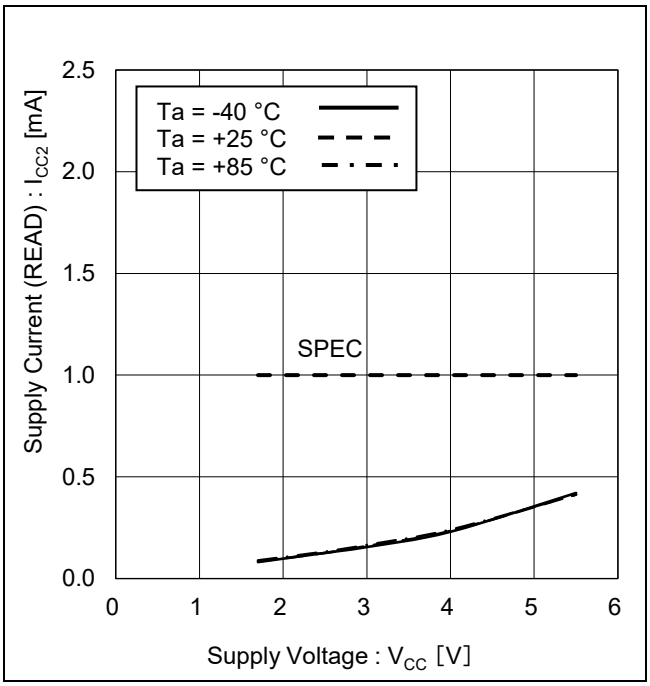

Figure 19. Supply Current (READ) vs Supply Voltage
I_{CC2} (READ, f_{SK} = 3 MHz)

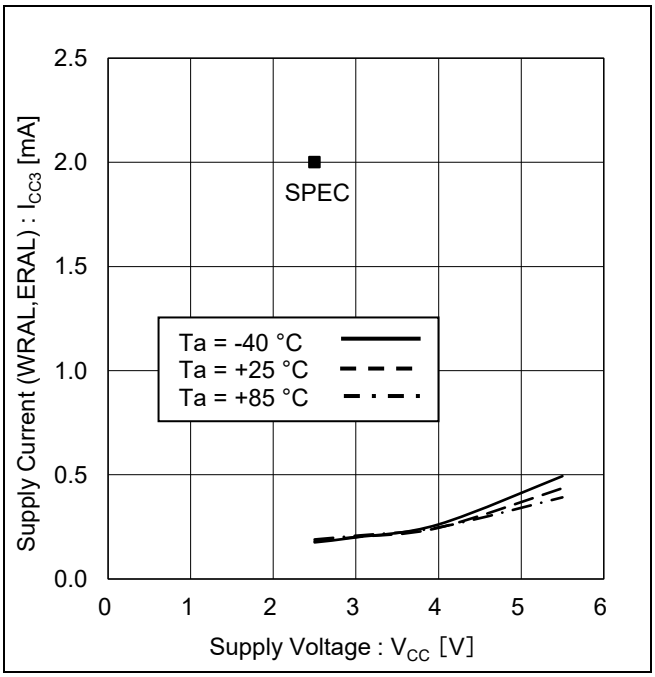

Figure 20. Supply Current (WRAL,ERAL) vs Supply Voltage
I_{CC3} (WRAL,ERAL, f_{SK} = 1 MHz)

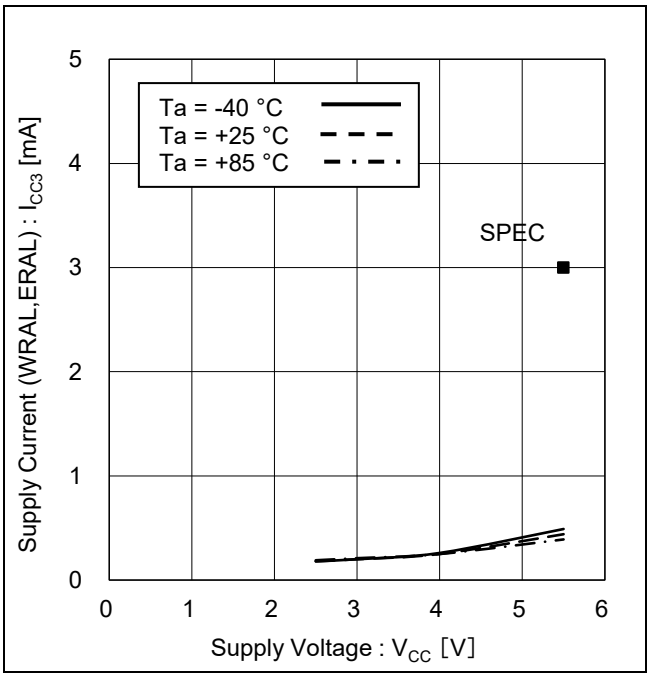

Figure 21. Supply Current (WRAL,ERAL) vs Supply Voltage
I_{CC3} (WRAL,ERAL, f_{SK} = 3 MHz)

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Typical Performance Curves - continued

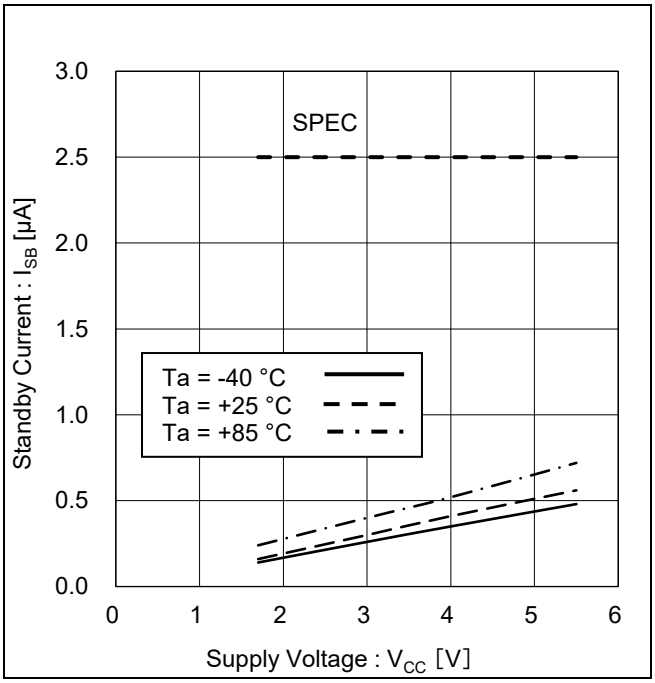

Figure 22. Standby Current vs Supply Voltage

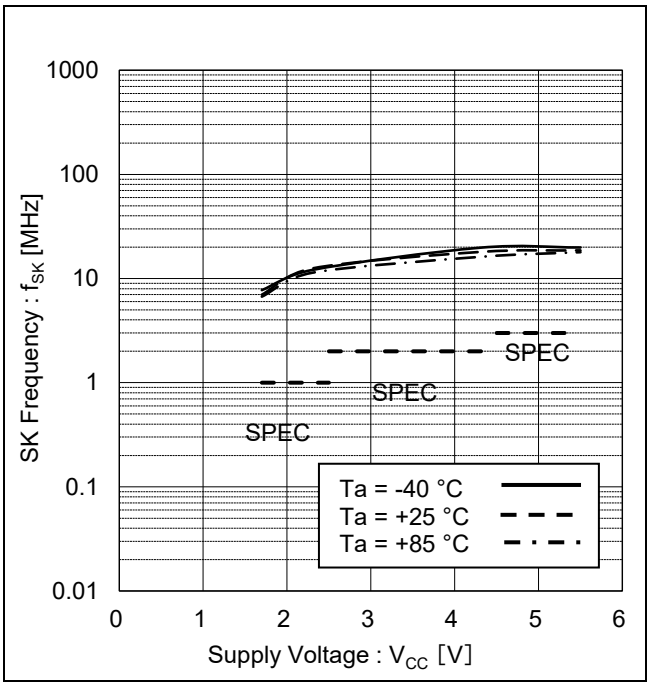

Figure 23. SK Frequency vs Supply Voltage

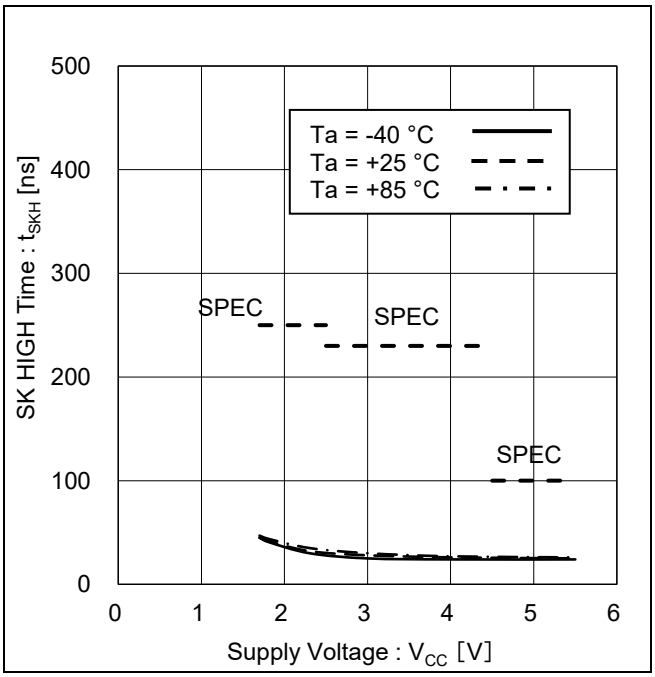

Figure 24. SK HIGH Time vs Supply Voltage

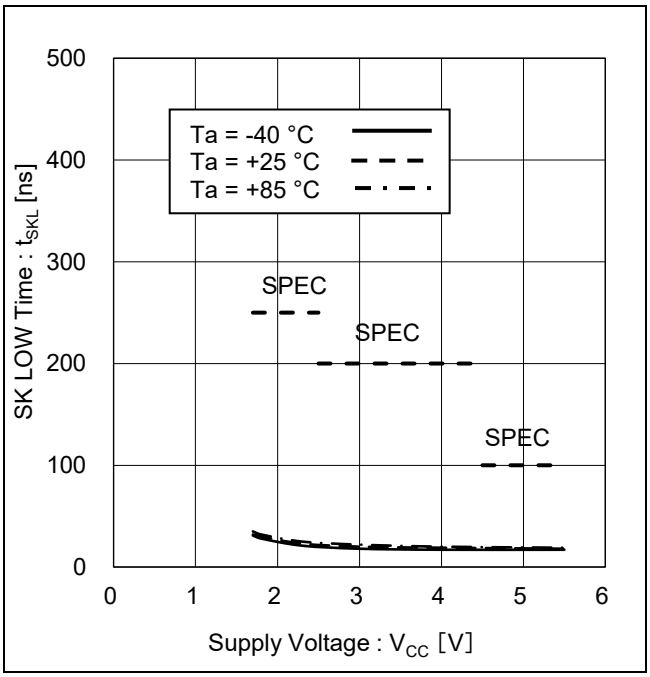

Figure 25. SK LOW Time vs Supply Voltage

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Typical Performance Curves - continued

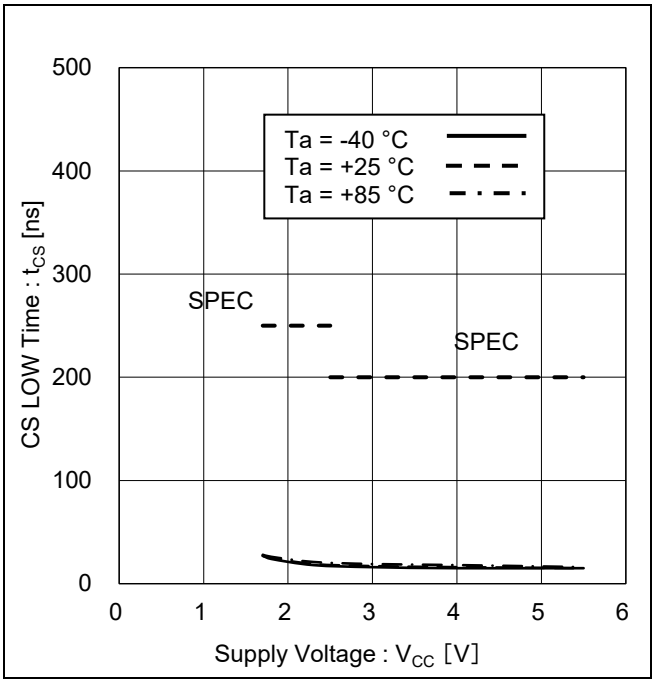

Figure 26. CS LOW Time vs Supply Voltage

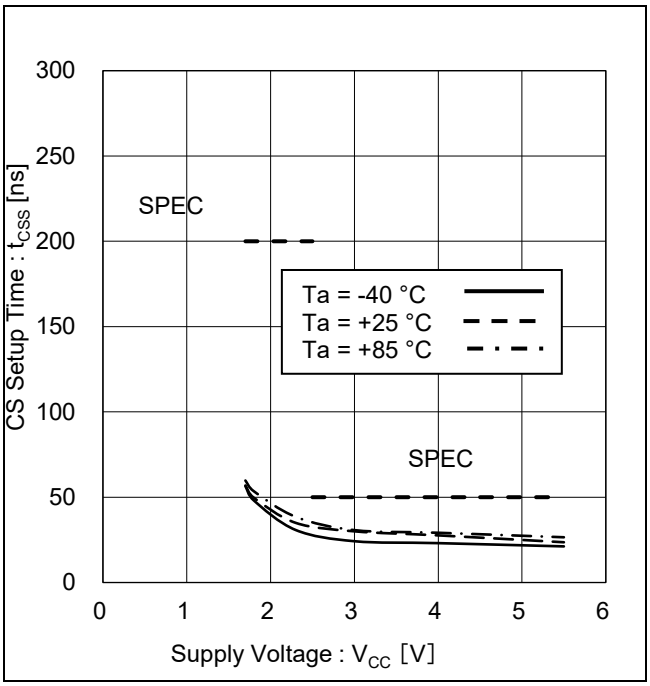

Figure 27. CS Setup Time vs Supply Voltage

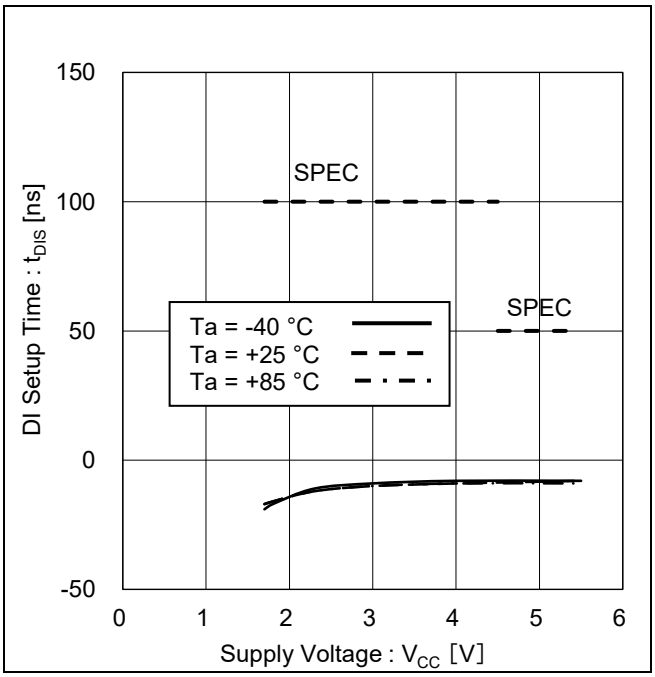

Figure 28. DI Setup Time vs Supply Voltage

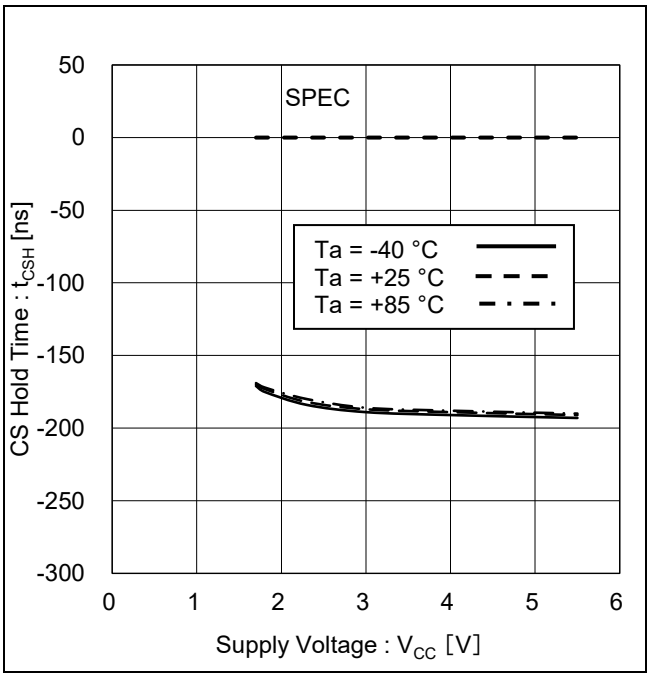

Figure 29. CS Hold Time vs Supply Voltage

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Typical Performance Curves - continued

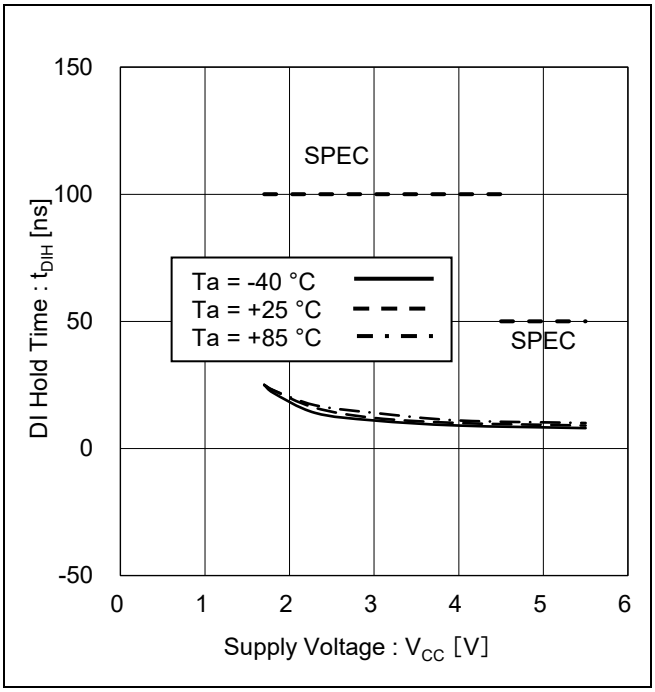

Figure 30. DI Hold Time vs Supply Voltage

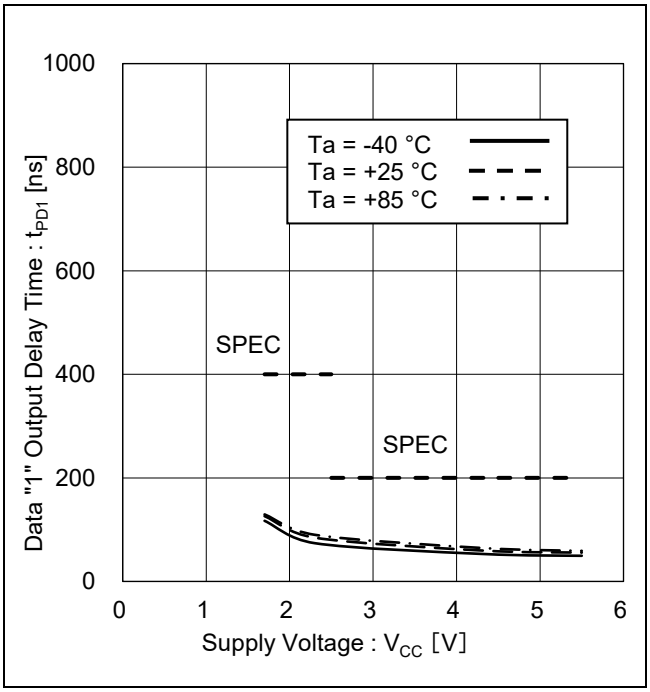

Figure 31. Data "1" Output Delay Time vs Supply Voltage

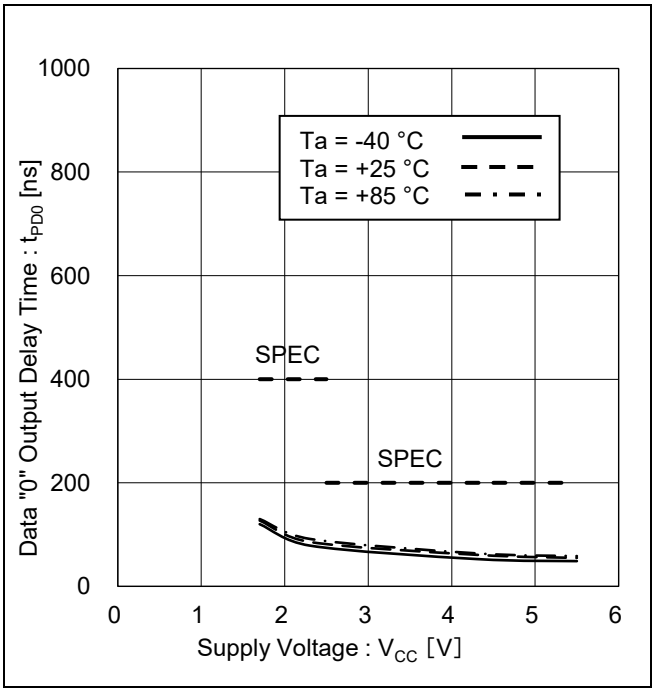

Figure 32. Data "0" Output Delay Time vs Supply Voltage

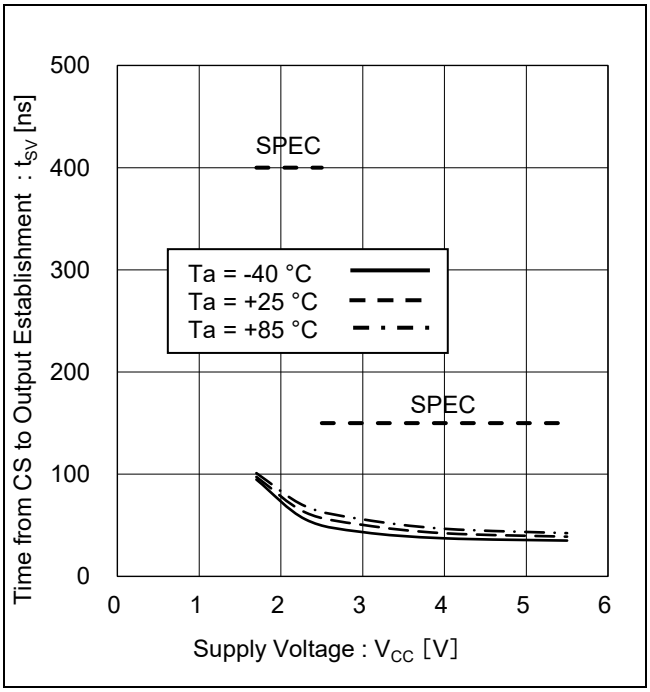

Figure 33. Time from CS to Output Establishment vs Supply Voltage

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Typical Performance Curves - continued

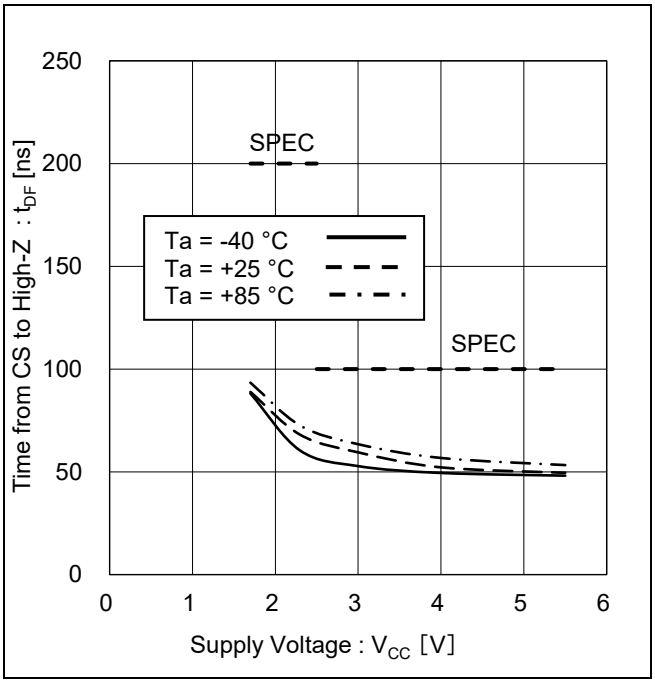

Figure 34. Time from CS to High-Z vs Supply Voltage

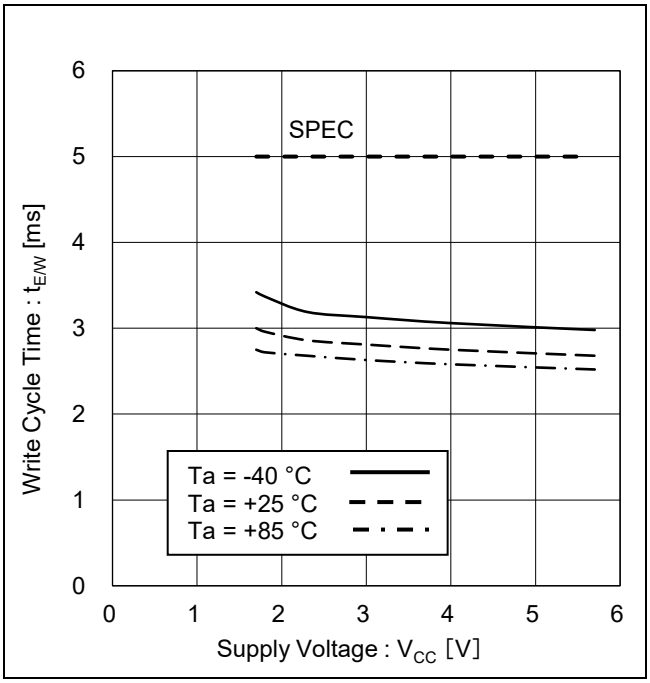

Figure 35. Write Cycle Time vs Supply Voltage

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Description of Operation

Communications of the MicroWire BUS are carried out by SK (serial clock), DI (serial data input), DO (serial data output), and CS (chip select) for device selection. In connecting one EEPROM to a microcontroller, connect it as shown in Figure 36-(a) or Figure 36-(b). And, when using the input and output common I/O port of the microcontroller, connect DI and DO via a resistor as shown in Figure 36-(b), wherein connection by 3 lines is possible. In case of using multiple EEPROM devices, refer to Figure 36-(c).

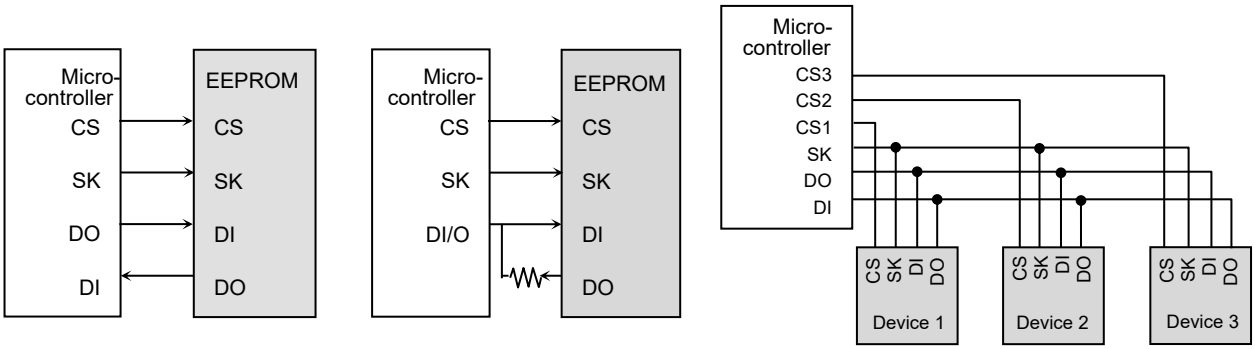

Figure 36-(a). Connection by 4 lines

Figure 36-(b). Connection by 3 lines

Figure 36-(c). Connection example of multiple devices

Figure 36. Connection Methods with Microcontroller

Communications of the MicroWire BUS are started by the first “1” input after the rise of CS. This input is called the “Start Bit”. After input of the start bit, the “Opcode”, Address, and Data are then inputted consecutively. Address and Data are all inputted with MSB first. All “0” signal inputs after the rise of CS up to the start bit is ignored. Therefore, if there is a limitation in the bit width of PIO of the microcontroller, it is possible to input “0” before the start bit to control the bit width.

Command Mode

Command	Start bit	Op code	Address	Data
Read (READ) *1	1	10	* A6,A5,A4,A3,A2,A1,A0	D15 to D0 (READ DATA)
Write enable (WEN)	1	00	1 1 * * * * * *	-
Write (WRITE) *2	1	01	* A6,A5,A4,A3,A2,A1,A0	D15 to D0 (WRITE DATA)
Write all (WRAL) *2	1	00	0 1 * * * * * *	D15 to D0 (WRITE DATA)
Write disable (WDS)	1	00	0 0 * * * * * *	-
Erase (ERASE)	1	11	* A6,A5,A4,A3,A2,A1,A0	-
Erase all (ERAL)	1	00	1 0 * * * * * *	-

・Input the address and the data in MSB-first order.
・As for *, input either V_{IH} or V_{IL}.

*Start bit
Acceptance of all the commands of this IC starts at recognition of the start bit. The “Start Bit” means the first “1” input after the rise of CS.

*1 For READ, after setting the command, the data output of the selected address starts. Then, in a sequential order of addresses, the data of the next address will be output, and will continuously output data of succeeding addresses with the use of a continuous SK clock input. (Auto-Increment Function)

*2 When the WRITE and WRAL commands are executed, the previous data written in the selected memory cell is automatically deleted first, then the input data is written next.

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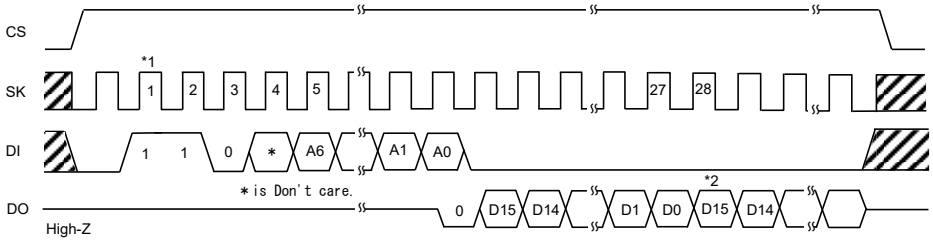
Timing Chart

1. Read Cycle (READ)



*1 Start bit
When data "1" is input for the first time after the rise of CS, this is recognized as a start bit. And, even if multiple "0" are input after the rise of CS, the first "1" input will still be recognized as the start bit, and the following operation starts. This is common to all the commands that will be discussed hereafter.
*2 The succeeding address' data output (Auto-Increment Function)

Figure 37. Read Cycle

When the READ command is recognized, the data (16 bit) of the selected address is output to serial. At that time, "0" (dummy bit) is output first, in sync with address bit A0 and with the rise of SK. After which, the main data is output in sync with the rise of SK. This IC has Address Auto Increment Function available only for READ command. wherein after executing READ command on the first selected address, the data of the next address is read. And this will continue in a sequential order of addresses with the use of a continuous SK clock input, and by keeping CS at HIGH during auto-increment.

2. Write Cycle (WRITE)

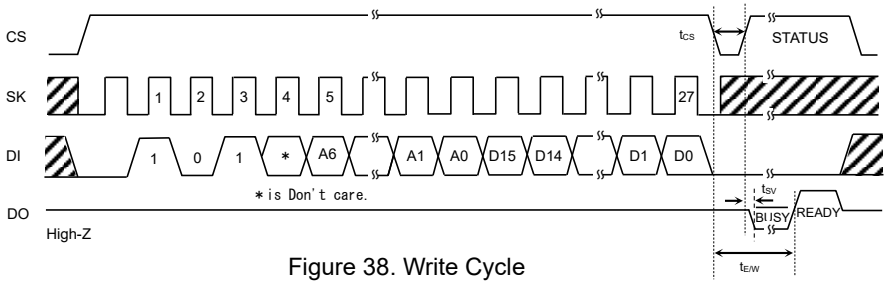


Figure 38. Write Cycle

In this command, input 16 bit data (D15 to D0) is written to a designated address (A6 to A0). The actual write starts from the fall of CS, after D0 is sampled with SK clock (27 th clock from the start bit input), to the rise of the 28 th clock. When STATUS is not detected (CS = LOW fixed), WRITE time is 5 ms (Max) in conformity with $t_{E/W}$. And when STATUS is detected (CS = HIGH), all commands are not accepted for areas where LOW ($\overline{BUSY}$) is output from DO. Therefore, do not input any command.

3. Write All Cycle (WRAL)

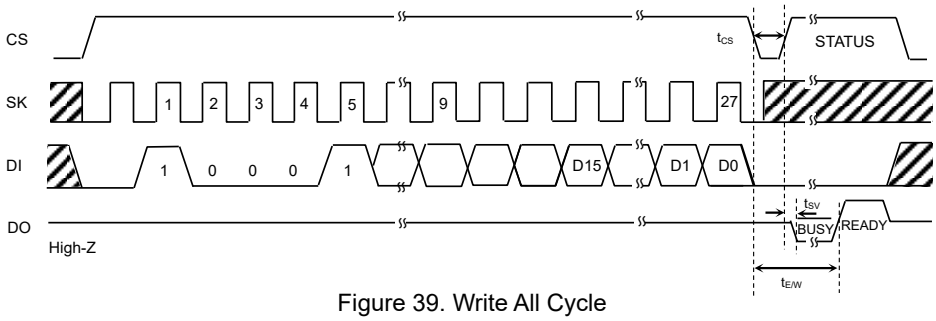


Figure 39. Write All Cycle

In this command, input 16 bit data is written simultaneously. Data is written in bulk, rather than being written sequentially one word at a time, with a write time of only 5 ms (Max) in conformity with $t_{E/W}$. WRAL can detect the STATUS in the same manner as WRITE.

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Timing Chart - continued

4. Write Enable (WEN)/Disable (WDS) Cycle

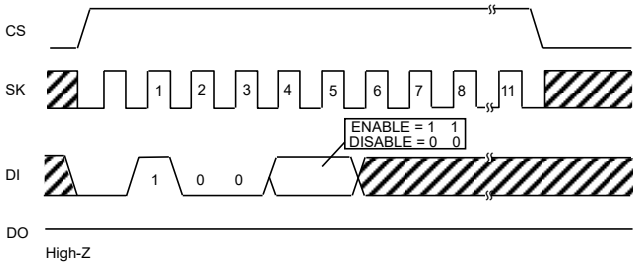

Figure 40. Write Enable (WEN)/Disable (WDS) Cycle

At power on, this IC is in Write Disable status by the internal RESET circuit. Before executing the WRITE command, it is necessary to execute the Write Enable Command first. And, once this command is executed, writing is valid until the Write Disable Command is executed or the power is turned off. However, the READ command is valid regardless of whether Write Enable/Disable command is executed. Input to SK after 6 clocks of this command is available by either HIGH or LOW, but be sure to input it. When the Write Enable Command is executed after power on, Write Enable status gets in. When the Write Disable command is executed then, the IC gets in Write Disable Status the same as at power on, and then the WRITE command is canceled thereafter in software manner. However, the READ command is still executable. In Write Enable status, even when the WRITE command is input by mistake, writing will still start. To prevent such a mistake, it is recommended to execute the Write Disable command after the completion of each WRITE execution.

5. Erase Cycle (ERASE)

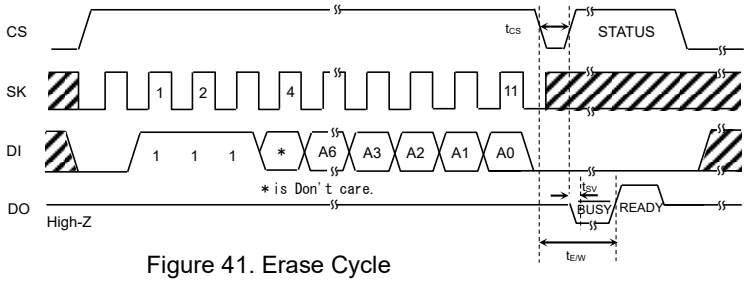

Figure 41. Erase Cycle

In this command, data of the designated address is made into “1”. The data of the designated address becomes “FFFFh”. Actual ERASE starts at the fall of CS after the rise of A0 taken SK clock. In ERASE, STATUS can be detected in the same manner as in WRITE command.

6. Erase all Cycle (ERAL)

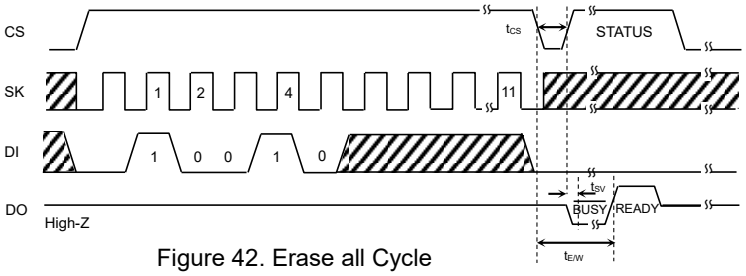

Figure 42. Erase all Cycle

In this command, data of all addresses is made into “1”. Data of all addresses becomes ”FFFFh”. Actual ERAL starts at the fall of CS after the rise of the 11 th clock from the start bit input. In ERAL, STATUS can be detected in the same manner as in WRITE command.

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Method to Cancel Each Command

1. READ
   Method to cancel: cancel by CS = LOW

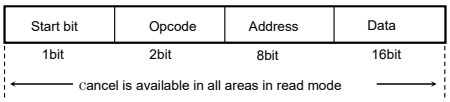

Figure 43. READ Cancel Available Timing

2. WRITE, WRAL
   a: From start bit to 27 th clock rise
   Cancel by CS = LOW.
   b: 27 th clock rise and after
   Cancellation is not available by any means.
   c: 28 th clock rise and after
   Cancel by CS = LOW.
   However, when write is started in b area (CS is ended), cancellation is not available by any means.
   And when SK clock is input continuously, cancellation is not available.

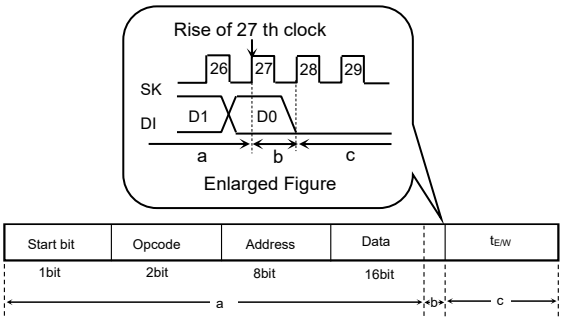

Figure 44. WRITE, WRAL Cancel Available Timing

*1) If V_{CC} is turned OFF in this area, designated address data is not guaranteed. Therefore, it is recommended to execute WRITE once again.
*2) If CS is started at the same timing as that of the SK rise, write execution/cancel becomes unstable. Therefore, it is recommended to bring CS to LOW in SK = LOW area. As for SK rise, recommend timing is t_{SKH} or more.

3. ERASE, ERAL
   a: From start bit to 11 th clock rise
   Cancel by CS = LOW.
   b: 11 th clock rise and after
   Cancellation is not available by any means.
   c: 12 th clock rise and after
   Cancel by CS = LOW.
   However, when write is started in b area (CS is ended), cancellation is not available by any means.
   And when SK clock is input continuously, cancellation is not available.

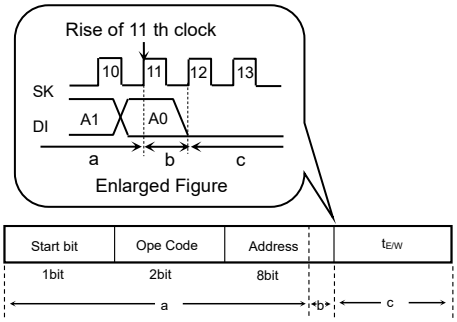

Figure 45. ERASE, ERAL Cancel Available Timing

*1) If V_{CC} is turned OFF in this area, designated address data is not guaranteed. Therefore, it is recommended to execute WRITE once again.
*2) If CS is started at the same timing as that of the SK rise, write execution/cancel becomes unstable. Therefore, it is recommended to bring CS to LOW in SK = LOW area. As for SK rise, recommend timing is t_{SKH} or more.

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Application Examples

1. READY/$\overline{\text{BUSY}}$ Status Display (DO Pin)
   This display outputs the internal status signal. When CS rises after t_{CS} from CS fall after write command input, HIGH or LOW output.

   R/$\overline{\text{B}}$ display = LOW ($\overline{\text{BUSY}}$) = write in progress
   (DO Status)
   After the timer circuit in the IC works and creates the period of $t_{E/W}$, this time circuit completes automatically. And operates in the period of $t_{E/W}$, and during this period, other command are not accepted.

   R/$\overline{\text{B}}$ display = HIGH (READY) = command wait status
   (DO Status)
   The memory cell write operation is completed, and the next command is accepted even within $t_{E/W}$ (Max 5 ms). Therefore, CS = HIGH in the period of $t_{E/W}$, and when signals are input to SK and DI malfunction may occur. Therefore, set DI = LOW in the area CS = HIGH. (Especially, in the case of shared input port, attention is required.)

   *Do not input any command while status signal is output. Command input in $\overline{\text{BUSY}}$ area is canceled, but command input in READY area is accepted. Therefore, status READY output is canceled, and malfunction and write error may be made.

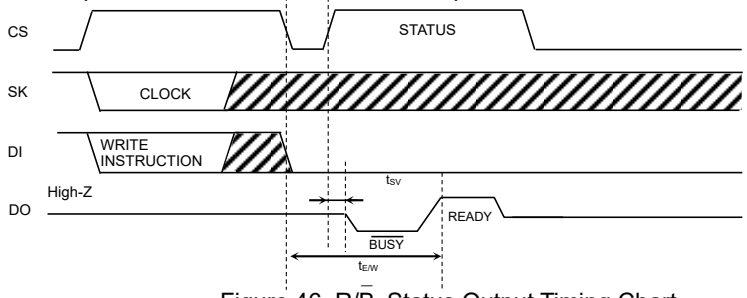
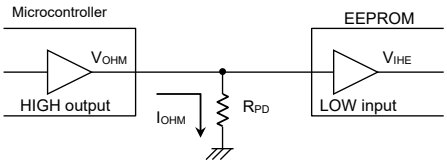


Figure 46. R/$\overline{\text{B}}$ Status Output Timing Chart

2. At standby
   When CS is LOW, even if SK, DI, DO are LOW, HIGH or with middle electric potential, current does not over I_{SB} Max.

3. Pull Down CS
   By making CS = LOW at power ON/OFF, malfunction and write error are prevented. Select an appropriate pull down resistance value from microcontroller's V_{OH}, I_{OH} and this IC's V_{IH} characteristics.



V_{IHE} : EEPROM V_{IH} specifications
V_{OHM} : Microcontroller V_{OH} specifications
I_{OHM} : Microcontroller I_{OH} specifications

Figure 47. CS Pull Down Resistance

$$R_{PD} \geq \frac{V_{OHM}}{I_{OHM}} \quad (1)$$

$$V_{OHM} \geq V_{IHE} \quad (2)$$

Example) When V_{CC} = 5 V, V_{IHE} = V_{CC} x 0.7 V, V_{OHM} = 4.0 V, I_{OHM} = 2 mA, from equation (1),

$$R_{PD} \geq \frac{4.0}{2 \times 10^{-3}}$$

$$R_{PD} \geq 2.0 \ [\text{k}\Omega]$$

With the value of R_{PD} satisfying the equation above, V_{OHM} becomes 4.0 V or more, and with V_{IHE} (= 3.5 V), equation (2) is also satisfied.

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Application Examples - continued

4. Pull Up and Pull Down of DO

DO is available for both pull up and pull down. DO output is High-Z except during READY/$\overline{\text{BUSY}}$ output timing in WRITE command and, after data output at READ command. When malfunction occurs at High-Z input of the microcontroller port connected to DO, it is necessary to pull down or pull up DO. When there is no influence upon the microcontroller actions, DO may be left OPEN. If DO is OPEN during a transition of output from $\overline{\text{BUSY}}$ to READY status, and at an instance where CS = HIGH, SK = HIGH, DI = HIGH, EEPROM recognizes this as a start bit, resets READY output, and sets DO = High-Z. Therefore, READY signal cannot be detected. To avoid such output, pull up the DO pin for improvement.

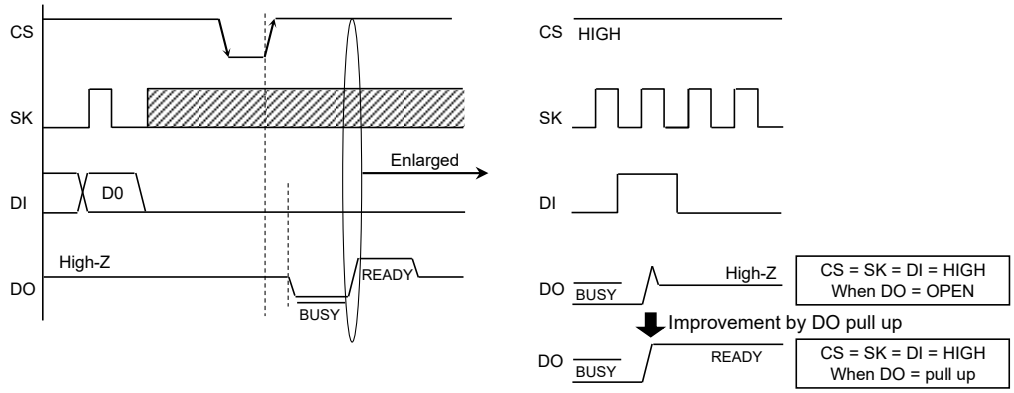
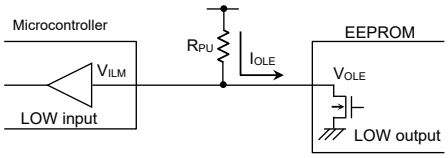


Figure 48. Ready Output Timing at DO = OPEN

As for pull-up and pull-down resistance value of DO, select an appropriate value based on the V_{IH} and V_{IL} of the microcontroller and the V_{OH}, I_{OH}, V_{OL} and I_{OL} characteristics of this IC.



V_{OLE} : EEPROM V_{OL} specifications
V_{ILM} : Microcontroller V_{IL} specifications
I_{OLE} : Microcontroller I_{OL} specifications

Figure 49. DO Pull up Resistance

$$R_{PU} \geq \frac{V_{CC} - V_{OLE}}{I_{OLE}} \quad (3)$$

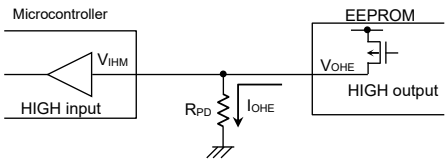
$$V_{OLE} \leq V_{ILM} \quad (4)$$

Example) When V_{CC} = 5 V, V_{OLE} = 0.4 V, I_{OLE} = 2.1 mA, V_{ILM} = 0.8 V, from the equation (3),

$$R_{PU} \geq \frac{5 - 0.4}{2.1 \times 10^{-3}}$$

$$R_{PU} \geq 2.2 \ [\text{k}\Omega]$$

With the value of R_{PU} to satisfy the above equation, V_{OLE} becomes 0.4 V or below, and with V_{ILM} (= 0.8 V), the equation (4) is also satisfied.



V_{OHE} : EEPROM V_{OH} specifications
I_{OHE} : EEPROM I_{OH} specifications
V_{IHM} : Microcontroller V_{IH} specifications

Figure 50. DO Pull down Resistance

$$R_{PD} \geq \frac{V_{OHE}}{I_{OHE}} \quad (5)$$

$$V_{OHE} \geq V_{IHM} \quad (6)$$

Example) When V_{CC} = 5 V, V_{OHE} = V_{CC} - 0.2 V, I_{OHE} = 0.1 mA, V_{IHM} = V_{CC} x 0.7 V from the equation (5)

$$R_{PD} \geq \frac{5 - 0.2}{0.1 \times 10^{-3}}$$

$$R_{PD} \geq 48 \ [\text{k}\Omega]$$

With the value of R_{PD} to satisfy the above equation, V_{OHE} becomes 4.8 V or more, and with V_{IHM} (= 3.5 V) the equation (6) is also satisfied.

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Application Examples - continued

5. When to Directly Connect DI and DO

This IC has independent input pin DI and output pin DO, Signals are handled separately on timing chart. But by inserting a resistance R between the DI and DO pins, it is possible to carry out control by only 1 control line.

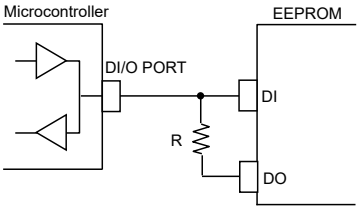

Figure 51. DI, DO Control Line Common Connection

5.1 Data collision of microcontroller DI/O output and DO output and feedback of DO output to DI input.

Drive from the microcontroller DI/O output to DI input on I/O timing, and signal output from DO output occur at the same time in the tow cases.

5.1.1 1 clock cycle to take in A0 address data at read command

Dummy bit “0” is output to the DO pin. When address data A0 = “1” input, through current route occurs.

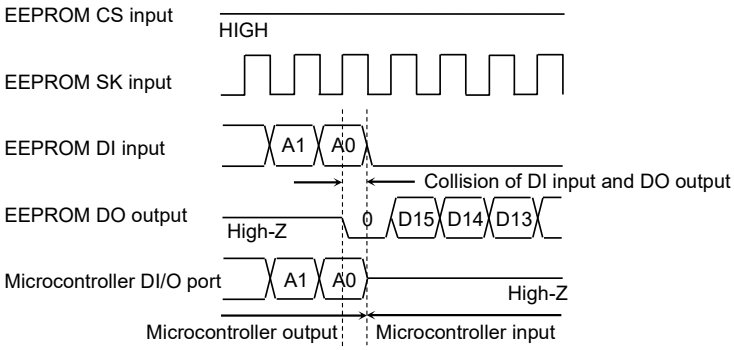

Figure 52. Collision Timing at Read Data Output at DI, DO Direct Connection

5.1.2 Timing of CS = HIGH after write command. The DO pin in READY/$\overline{\text{BUSY}}$ output

When the next start bit input is recognized, High-Z gets in. Especially, at command input after write, when CS input is started with microcontroller DI/O output LOW, READY output HIGH is output from the DO pin, and through current route occurs. Feedback input at timing of these 5.1.1 and 5.1.2 does not cause disorder in basic operations, if resistance R is inserted.

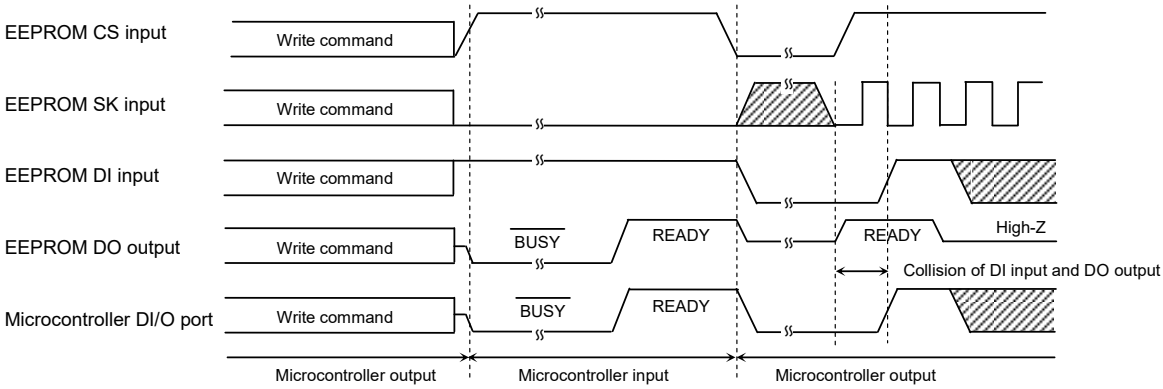

Figure 53. Collision Timing at DI, DO Direct Connection During Write Operation

Note) As for the case 5.1.2, attention must be paid to the following

When STATUS READY is output, DO and DI are shared, DI = HIGH and the microcontroller DI/O = High-Z or the microcontroller DI/O = HIGH, if SK clock is input, DO output is input to DI and is recognized as a start bit, and malfunction may occur. As a method to avoid malfunction, at STATUS READY output, set SK = LOW, or start CS within 4 clocks after HIGH of READY signal is output.

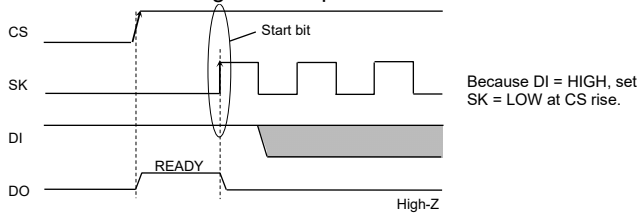

Figure 54. Start bit input timing at DI, DO direct connection

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Application Examples - continued

5.2 Selection of resistance value R

The resistance R becomes through current limit resistance at data collision. When through current flows, noises of power source line and instantaneous stop of power source may occur. When allowable through current is defined as I, the following relation should be satisfied. Determine allowable current amount in consideration of impedance and so forth of power source line in set. And insert resistance R, and set the value R to satisfy EEPROM input level V_{IH}/V_{IL}, even under influence of voltage decline owing to leak current and so forth. Insertion of R will not cause any influence upon basic operations.

5.2.1 Address Data A0 = "1" Input, dummy bit "0" Output Timing

(When microcontroller DI/O output is HIGH, EEPROM DO outputs LOW, and HIGH is input to DI)

・Make the through current to EEPROM 10 mA or below.

・See to it that the input level V_{IH} of EEPROM should satisfy the following.

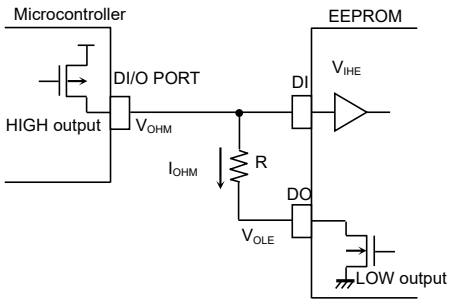

Figure 55. Circuit at DI, DO Direct Connection (Microcontroller DI/O HIGH output, EEPROM LOW output)

Condition

$$V_{IHE} \leq V_{OHM}$$
$$V_{IHE} \leq I_{OHM} \times R + V_{OLE}$$

At this moment, if V_{OLE} = 0 V,

$$V_{IHE} \leq I_{OHM} \times R$$

$$R \geq \frac{V_{IHE}}{I_{OHM}} \quad (7)$$

・V_{IHE} : EEPROM V_{IH} specifications
・V_{OLE} : EEPROM V_{OL} specifications
・V_{OHM} : Microcontroller V_{OH} specifications
・I_{OHM} : Microcontroller I_{OH} specifications

5.2.2 DO Status READY Output Timing

(When the microcontroller DI/O is LOW, EEPROM DO outputs HIGH, and LOW is input to DI)

・Set the EEPROM input level V_{IL} so as to satisfy the following.

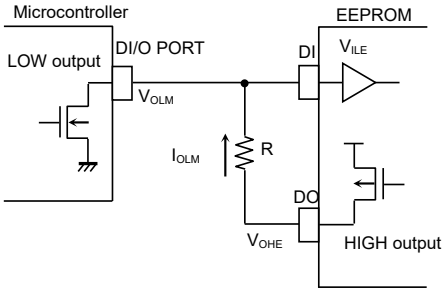

Figure 56. Circuit at DI, DO Direct Connection (Microcontroller DI/O LOW output, EEPROM HIGH output)

Condition

$$V_{ILE} \geq V_{OLM}$$
$$V_{ILE} \geq V_{OHE} - I_{OLM} \times R$$

As this moment, if V_{OHE} = V_{CC},

$$V_{ILE} \geq V_{CC} - I_{OLM} \times R$$

$$R \geq \frac{V_{CC} - V_{ILE}}{I_{OLM}} \quad (8)$$

・V_{ILE} : EEPROM V_{IL} specifications
・V_{OHE} : EEPROM V_{OH} specifications
・V_{OLM} : Microcontroller V_{OL} specifications
・I_{OLM} : Microcontroller I_{OL} specifications

Example) When V_{CC} = 5 V, V_{IHE} = V_{CC} x 0.7 V, V_{ILE} = V_{CC} x 0.3 V, I_{OHM} = 0.4 mA, I_{OLM} = 2.1 mA,

From the equation (7),

$$R \geq \frac{V_{IHE}}{I_{OHM}}$$

$$R \geq \frac{3.5}{0.4 \times 10^{-3}}$$

$$R \geq 8.75\ [\mathrm{k\Omega}] \quad (9)$$

From the equation (8),

$$R \geq \frac{V_{CC} - V_{ILE}}{I_{OLM}}$$

$$R \geq \frac{5 - 1.5}{2.1 \times 10^{-3}}$$

$$R \geq 1.67\ [\mathrm{k\Omega}] \quad (10)$$

Therefore, from the equations (9) and (10),

$$R \geq 8.75\ [\mathrm{k\Omega}]$$

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I/O Equivalence Circuits

1. Input (CS)

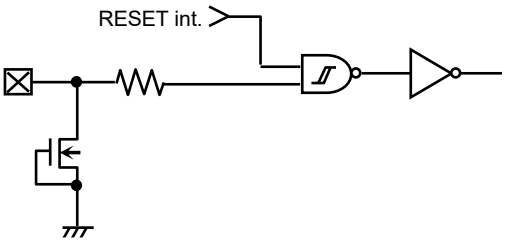

Figure 57. Input Equivalent Circuit (CS)

2. Input (SK)

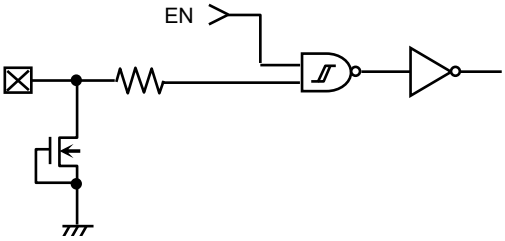

Figure 58. Input Equivalent Circuit (SK)

3. Input (DI)

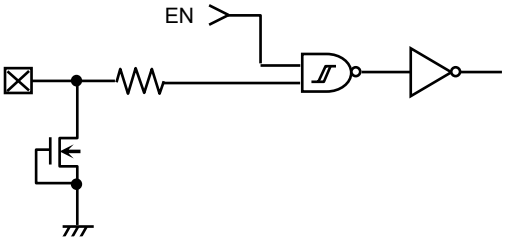

Figure 59. Input Equivalent Circuit (DI)

4. Output (DO)

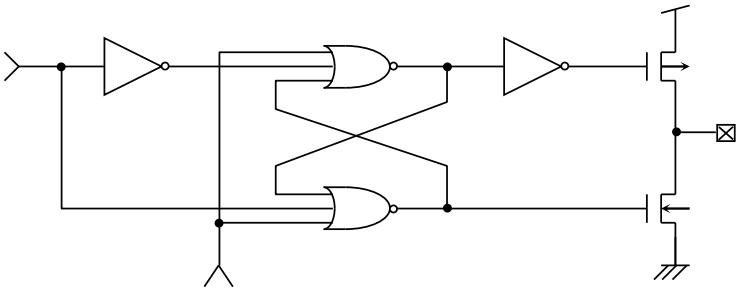

Figure 60. Output Equivalent Circuit (DO)

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Caution on Power-Up Conditions

At power-up, as the V_{CC} rises, the IC's internal circuits may go through unstable low voltage area, making the IC's internal circuit not completely reset, hence, malfunction like miswriting and misread may occur. To prevent it, this IC is equipped with Power-on Reset circuit. In order to ensure its operation, at power-up, please observe the conditions below. In addition, set the power supply rise so that the supply voltage constantly increases from V_{BOT} to V_{CC} level. Furthermore, t_{INIT} is the time from the power become stable to the start of the first command input.

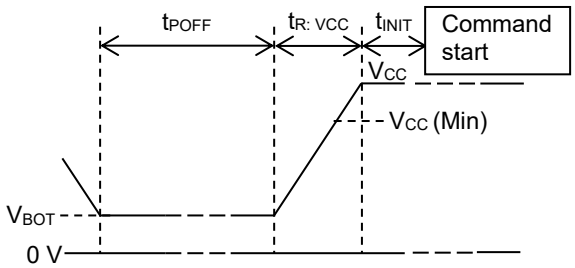

Figure 61. Rise Waveform Diagram

Power-Up Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage at Power OFF	V_{BOT}	-	-	0.3	V
Power OFF Time*(Note 15)*	t_{POFF}	1	-	-	ms
Initialize Time*(Note 15)*	t_{INIT}	0.1	-	-	ms
Supply Voltage Rising Time*(Note 15)*	$t_{R: VCC}$	0.001	-	100	ms

(Note 15) Not 100 % TESTED.

At power ON/OFF, set CS = LOW (= 0 V).
When CS is HIGH, this IC gets in input accept status (active). At power ON, set CS LOW to prevent malfunction from noise. (When CS is in LOW status, all inputs are canceled.) At power decline low power status may prevail. Therefore, at power OFF, set CS LOW to prevent malfunction from noise.

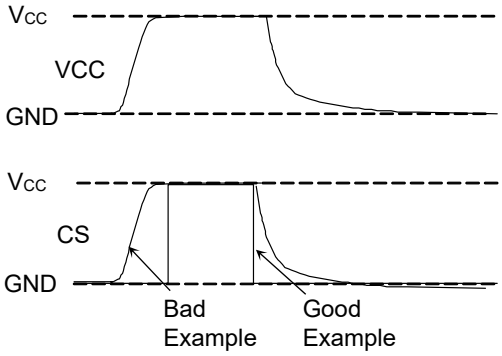

Figure 62. Timing at power ON/OFF

(Good example) The CS Pin is Low at power ON/OFF.
Set 1 ms or more to recharge at power OFF. When power is turned on without observing this condition, IC internal circuit may not be reset.

(Bad example) The CS Pin is pulled up to V_{CC}.
In this case, CS becomes HIGH (active status), EEPROM may malfunction or have write error due to noises. This is true even when CS input is High-Z.

Low Voltage Malfunction Prevention Function

LVCC circuit prevents data rewrite operation at low power, and prevents write error. At LVCC voltage (Typ = 1.2 V) or below, data rewrite is prevented.

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Noise Countermeasures

1. VCC Noise (bypass capacitor)
   When noise or surge gets in the power source line, malfunction may occur, therefore, for removing these, it is recommended to attach a bypass capacitor (0.1 μF) between IC VCC and GND. At this time, attach it as close to IC as possible. And, it is also recommended to attach a bypass capacitor between board VCC and GND.
2. SK Noise
   When the rise time (t_R) of SK is long, and a certain degree or more of noise exists, malfunction may occur owing to clock bit displacement. To avoid this, a Schmitt trigger circuit is built in SK input. The hysteresis width of this circuit is set about 0.2 V, if noises exist at SK input, set the noise amplitude 0.2 Vp-p or below. And it is recommended to set the rise time (t_R) of SK 100 ns or below. In the case when the rise time is 100 ns or more, take sufficient noise countermeasures. Make the clock rise, fall time as small as possible.

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Operational Notes

1. **Reverse Connection of Power Supply**
   Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. **Power Supply Lines**
   Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. **Ground Voltage**
   Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. **Ground Wiring Pattern**
   When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. **Operating Conditions**
   The function and operation of the IC are guaranteed within the range specified by the operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. **Inrush Current**
   When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. **Testing on Application Boards**
   When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. **Inter-pin Short and Mounting Errors**
   Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. **Unused Input Pins**
   Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

10. **Regarding the Input Pin of the IC**
    In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

11. **Ceramic Capacitor**
    When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

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Ordering Information

B	R	9	3	G	5	6	x	x	x	-	5	x	x	x

BUS Type
93 : MicroWire BUS

Ambient Operating Temperature /Supply Voltage
-40 °C to +85 °C
/1.7 V to 5.5 V

Capacity
56 = 2 Kbit

Package
FJ : SOP-J8
FVT : TSSOP-B8
FVM : MSOP8
NUX : VSN08AX2030A

5 : Process Code

Z : VSN08AX2030A
blank : SOP-J8, TSSOP-B8, MSOP8

Packaging and Forming Specification
E2 : Embossed tape and reel (SOP-J8, TSSOP-B8)
TR : Embossed tape and reel (MSOP8, VSN08AX2030A)

Lineup

Package		Orderable Part Number	
Type	Quantity		
SOP-J8	Reel of 2500	BR93G56FJ	-5E2
TSSOP-B8	Reel of 3000	BR93G56FVT	-5E2
MSOP8	Reel of 3000	BR93G56FVM	-5TR
VSN08AX2030A	Reel of 4000	BR93G56NUX	-5ZTR

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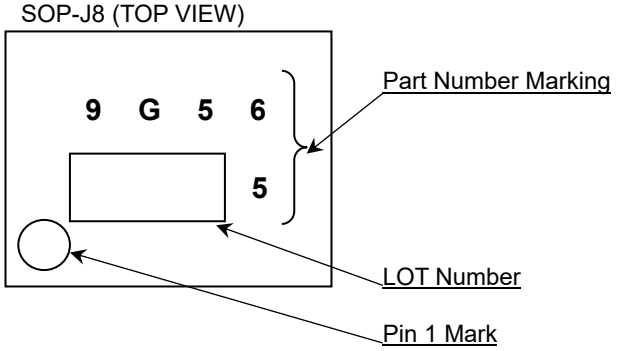
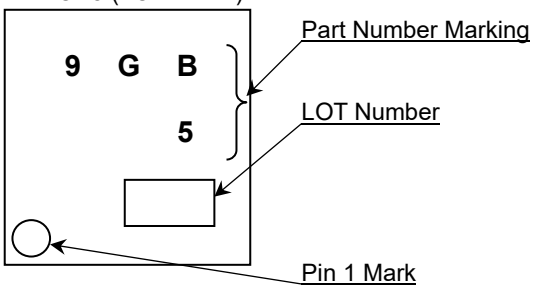
Marking Diagrams

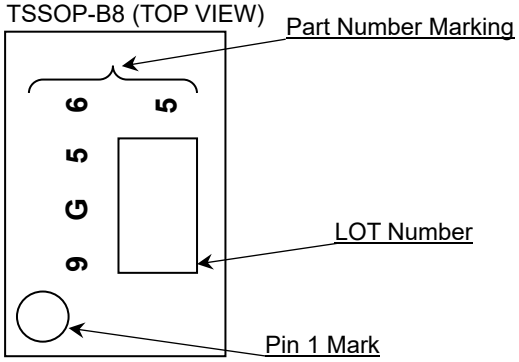
SOP-J8 (TOP VIEW)



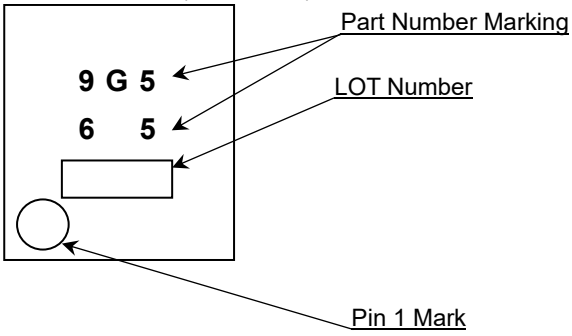
MSOP8 (TOP VIEW)



TSSOP-B8 (TOP VIEW)



VSN08AX2030A (TOP VIEW)



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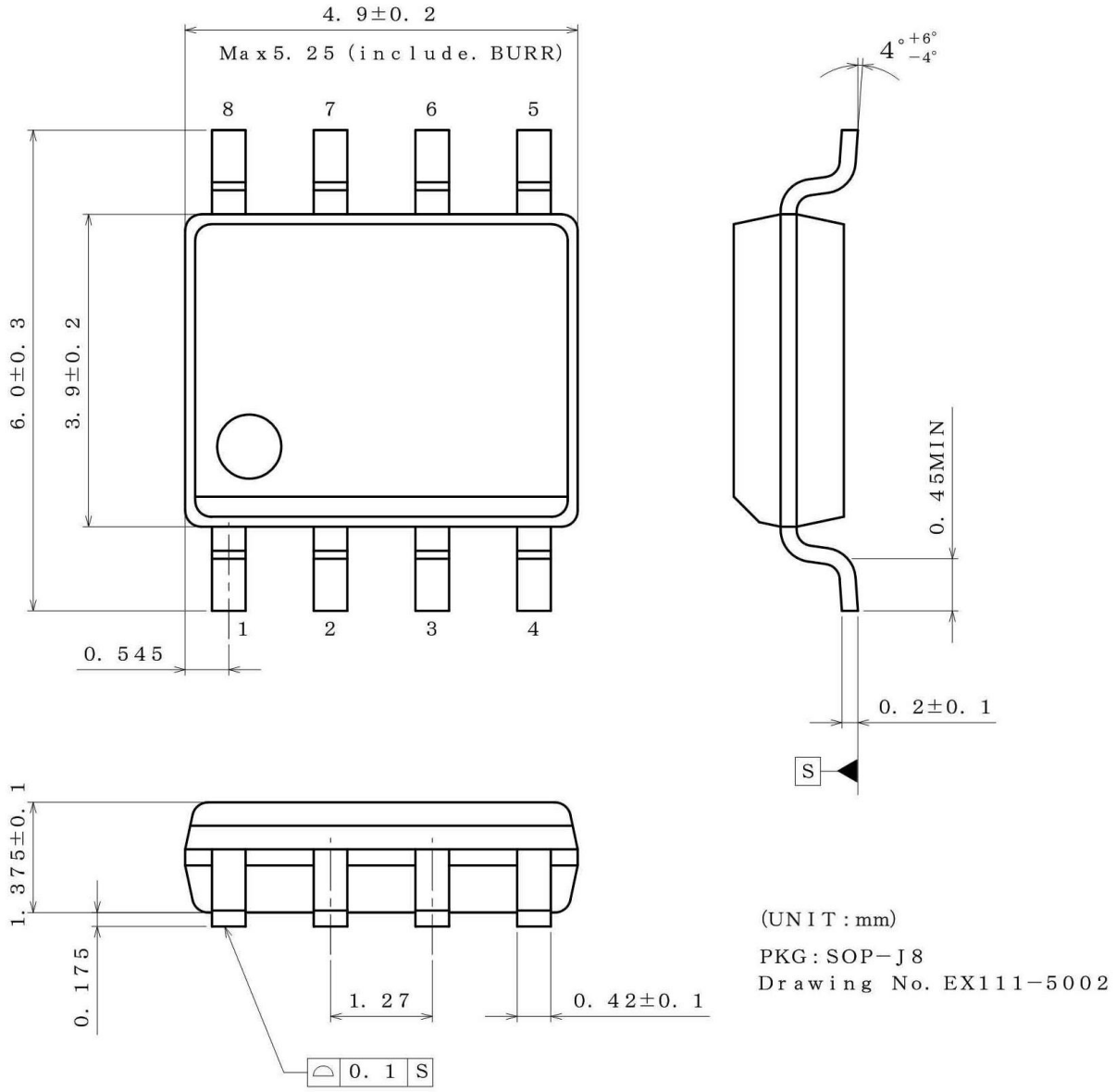
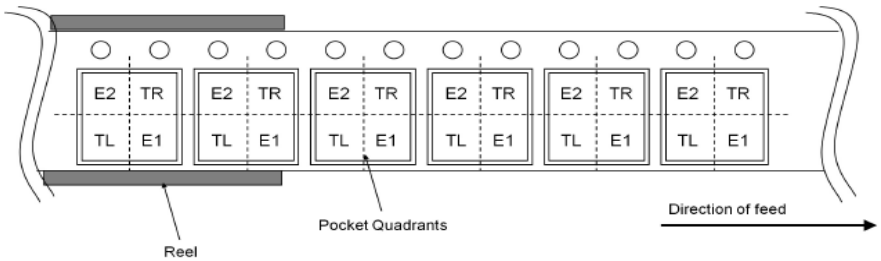
Physical Dimension and Packing Information

Package Name	SOP-J8



< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 The direction is the pin 1 of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand



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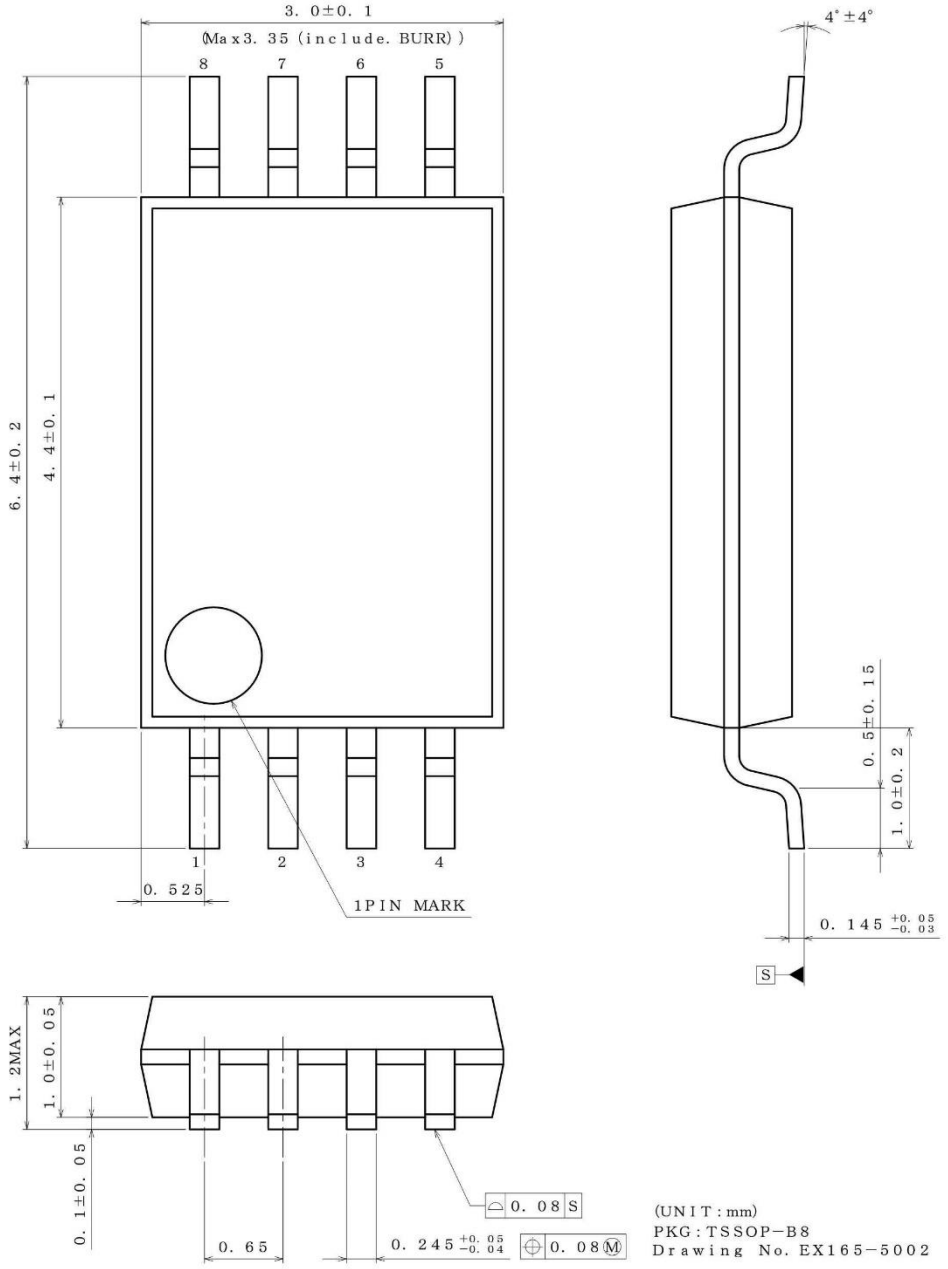
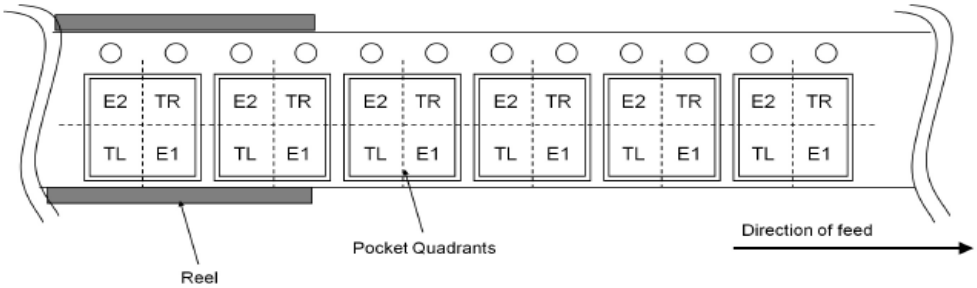
Physical Dimension and Packing Information - continued

Package Name	TSSOP-B8



< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	E2 The direction is the pin 1 of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand



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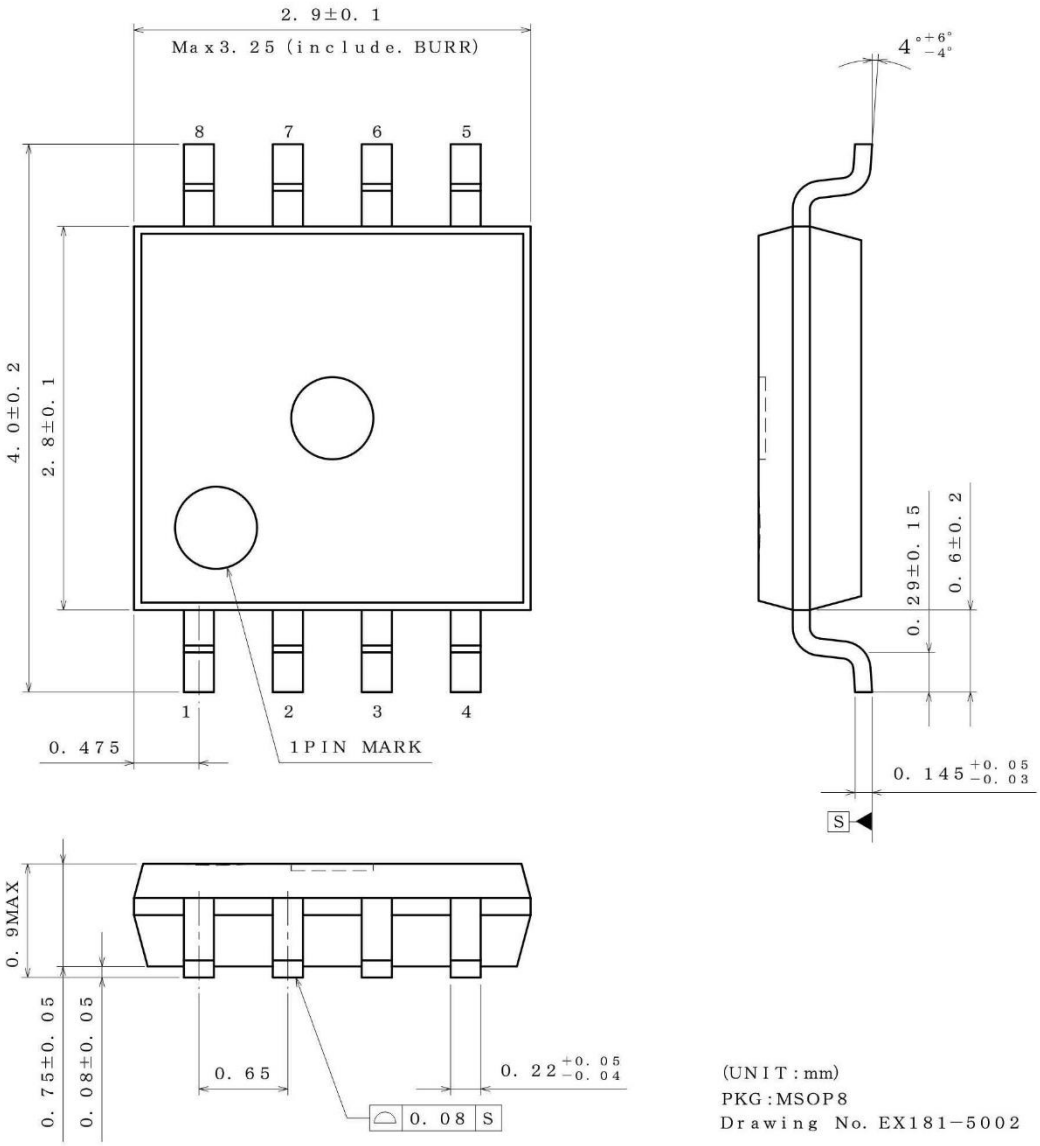
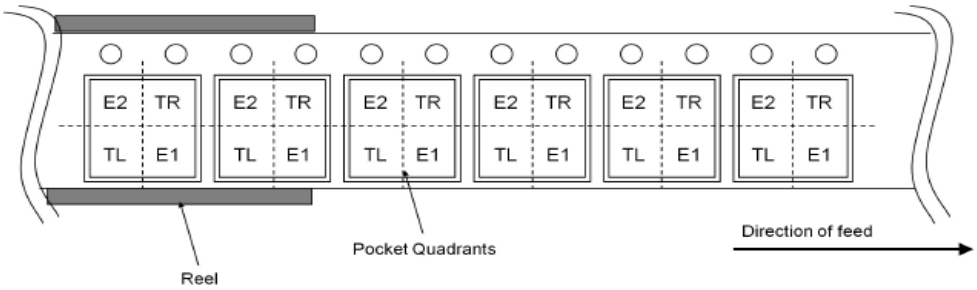
Physical Dimension and Packing Information - continued

Package Name	MSOP8



< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)



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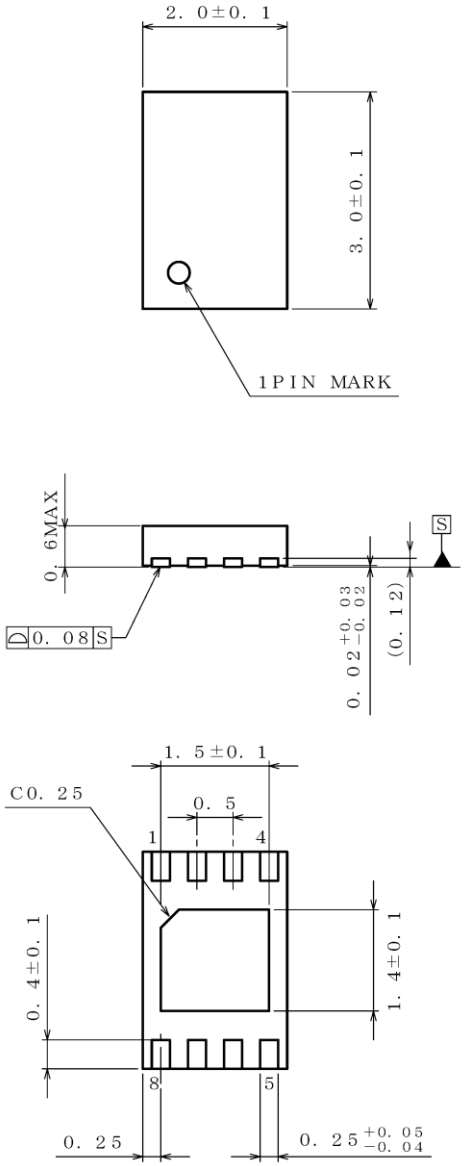
Physical Dimension and Packing Information - continued

Package Name	VSN08AX2030A

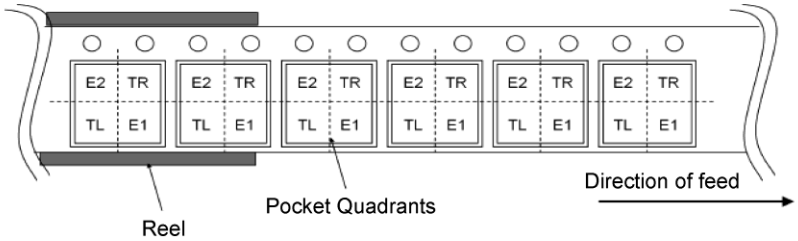


(UNIT : mm)

PKG : VSN08AX2030A
Drawing No. : EX001−0138

< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	4000pcs
Direction of feed	TR The direction is the pin 1 of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand



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Revision History

Date	Revision	Changes
26.Jun.2026	001	New Release

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Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   [a] Installation of protection circuits or other protective devices to improve system safety
   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application examples, their constants, software, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
   [b] the temperature or humidity exceeds those recommended by ROHM
   [c] the Products are exposed to direct sunshine or condensation
   [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

Precaution Regarding Intellectual Property Rights

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